



The Abdus Salam
International Centre for Theoretical Physics



2137-28

**Joint ICTP-IAEA Advanced Workshop on Multi-Scale Modelling for
Characterization and Basic Understanding of Radiation Damage
Mechanisms in Materials**

12 - 23 April 2010

**Molecular dynamics simulation of primary damage formation and phase
transformations in zirconium**

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Molecular dynamics simulation of primary damage formation and phase transformations in zirconium

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Motivation

Zirconium based alloys are a widely investigated materials due to applications in nuclear reactors and peculiar properties at phase transformations and plastic deformations

Two main alloys: Zircaloy and Zr-2.5Nb are poor neutron adsorber and are used as a nuclear fuel can material and for CANDU pressure tubes

Creep resistance of Zr-2.5Nb is good up to ~330 C

Creep ductility of Zircaloy is high: use as fuel can

The main problem is *radiation growth*

Mechanisms of c-loops nucleation?

Martensitic transformation

Outline

Diffusion of point defects

Martensitic Phase Transformation in Zr

Hysteretic behavior at reversible MT

Thermodynamics of MT and temperature T_0

Local structural order (LSO) parameter

Kinetics of transformation

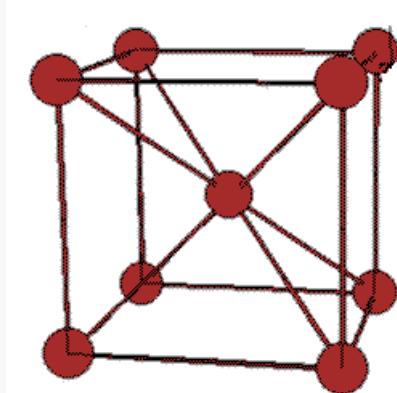
Heterogeneous nucleation on free surface

MT in polycrystalline Zr

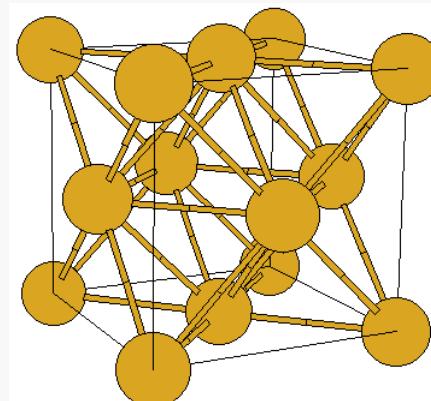
Primary damages in displacement cascades

Conclusions

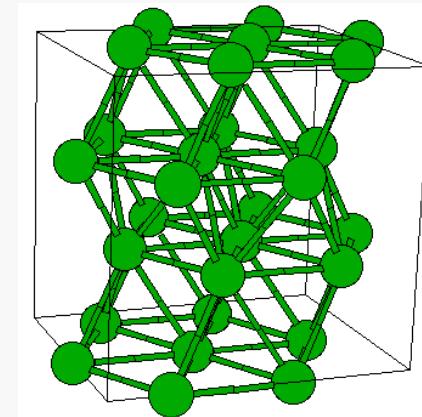
Most important Bravais lattices of simple metals



bcc



fcc

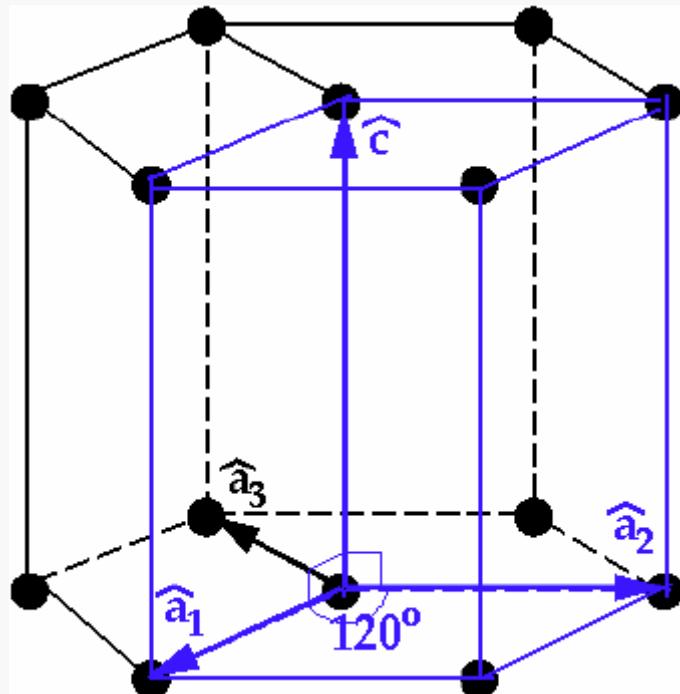


hcp

Simple metal lattice types

La	Ce fcc	Pr	Nd	Pm hcp	Sm	Eu bcc	Gd hcp	Tb hcp	Dy hcp	Ho hcp	Er hcp	Tm hcp	Yb fcc	Lu hcp
Ac fcc	Th fcc	Pa	U	Np	Pu	Am hcp	Cm hcp	Bk	Cf	Es	Fm	Md	No	Lr

Directions in HCP crystals

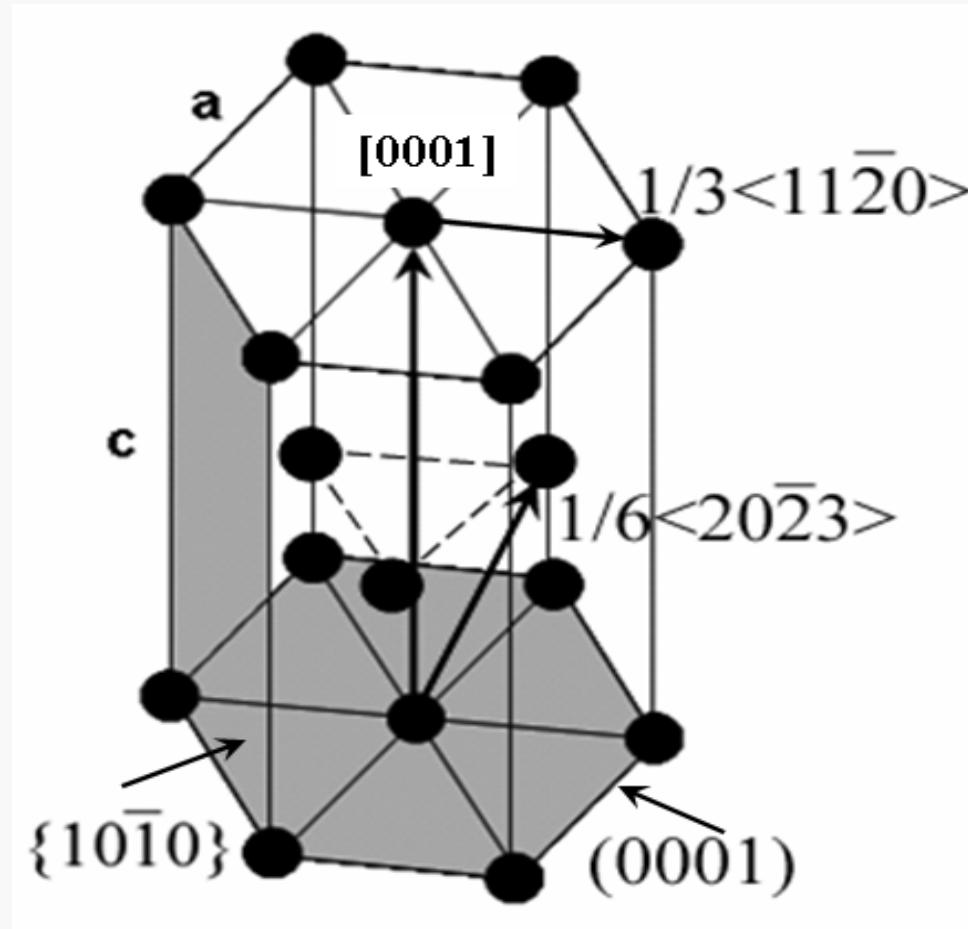


4-coordinate system is used:

$$[\hat{a}_1, \hat{a}_2, \hat{a}_3, c]$$

$$\hat{a}_3 = -(\hat{a}_1 + \hat{a}_2)$$

Indexes of some planes and directions in HCP lattice

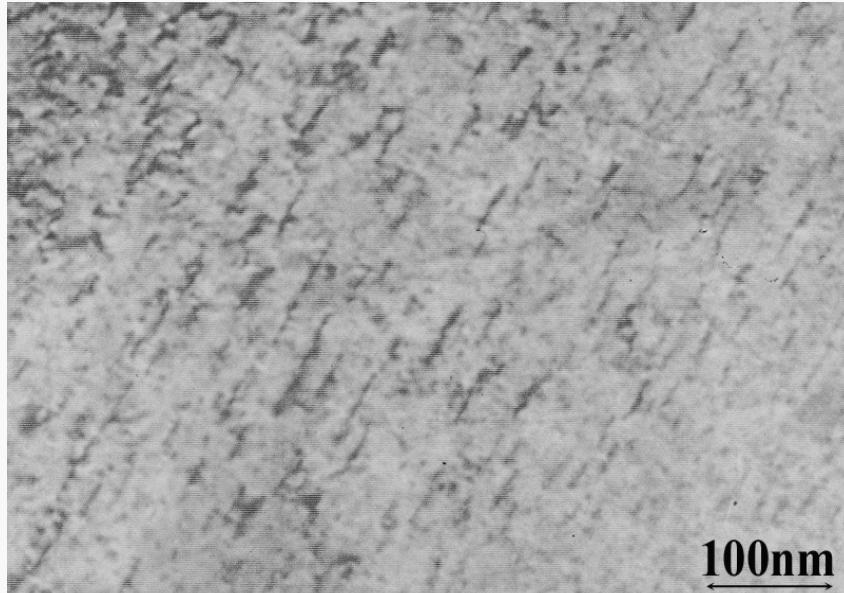


Dislocation loops in HCP crystals nucleated on prismatic $\{1010\}$, basal (0001) and pyramidal $\{1011\}$ planes have Burgers vectors $(1/3)<1120>$, $(1/6)<2023>$ or $(1/2)[0001]$ and $(1/3)<1123>$ respectively.

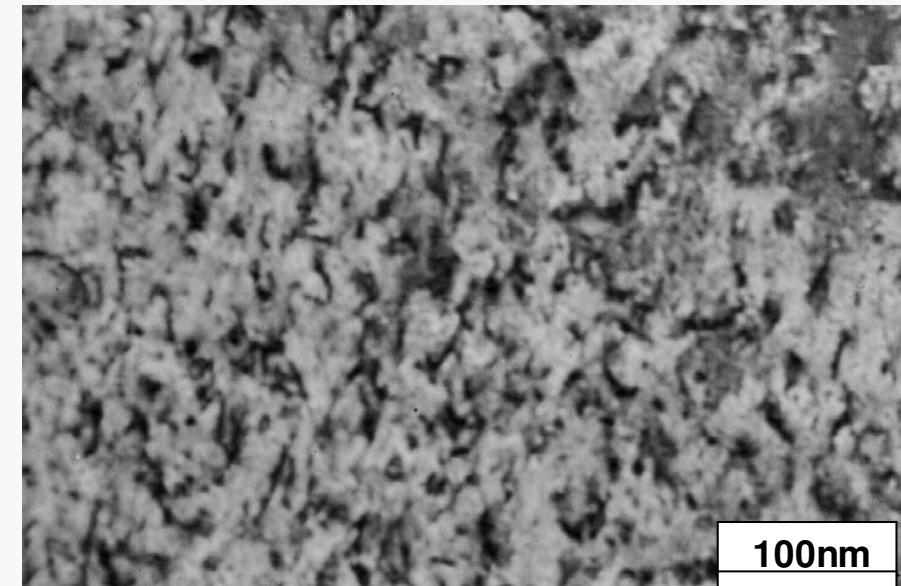
Oxygen influence on <c> loop nucleation

O.V. Borodin et al, Problems of Atomic Sc. Tech. (2008)

Zr⁶⁺, 15 dpa, T=550°C



Zr-1%Nb + 0,08% O₂



Zr-1%Nb + 0,19% O₂

The formation of <c>-loops is observed at low O₂ content.
Increasing of oxygen concentration up to 0,19% completely
suppress their nucleation.

Simulation Setup

Molecular Dynamics with Empirical force-field

$$\text{EAM potential: } U = \sum_{ij} V(r_{ij}) + \sum_i F(\bar{\rho}_i), \quad \bar{\rho}_i = \sum_j \phi(r_{ij})$$

Parameterization:

M.I. Mendelev, G.J. Ackland, Phil. Mag. Lett. 87 (2007) p. 349. (MA)

M. Igarashi, M. Khantha, V. Vitek, Phil. Mag. B63 (1991) 603. (IKV).

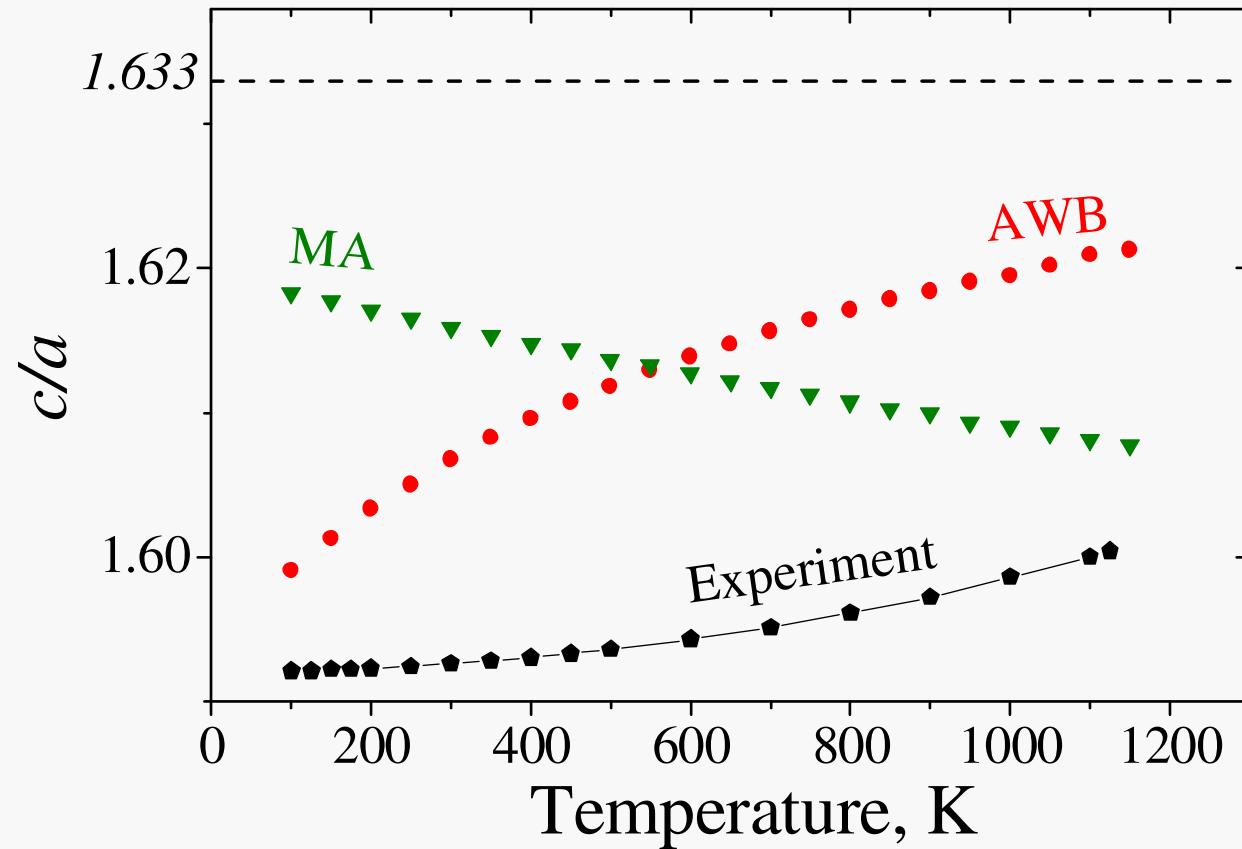
G.J. Ackland, S.J. Wooding, D.J. Bacon, Phil. Mag. A 71 (1995) 553 (AWB).

R.C. Pasianot, A.M. Monti, J. Nuclear Materials 264 (1999) 198. (PM)

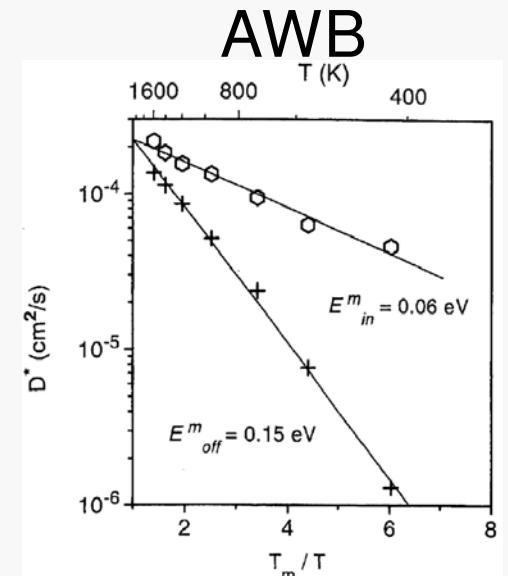
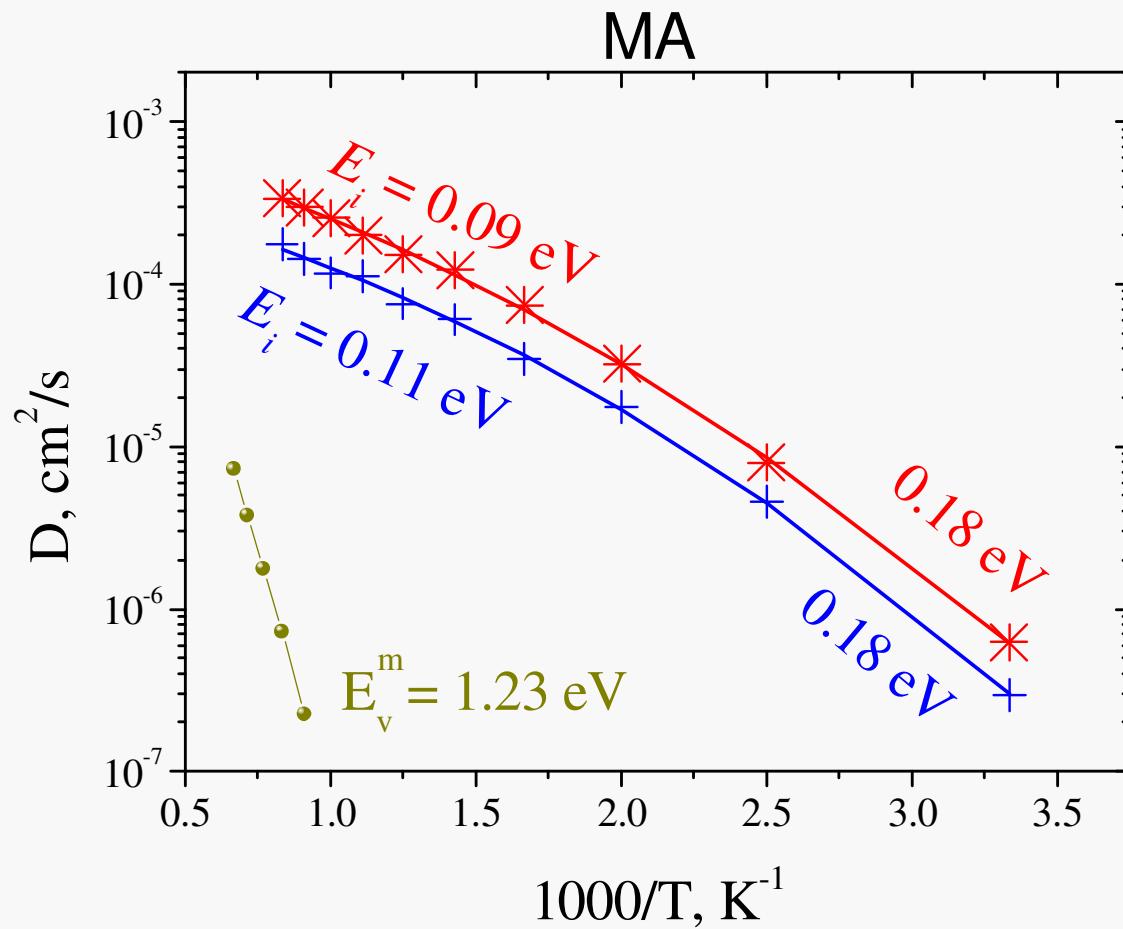
Physical properties calculated for various interatomic potentials

Property	Target value	AWB	PM	IKV	#1	#2	#3
a (hcp) (Å)	3.232 ¹	3.249	3.232	3.232	3.231	3.220	3.234
c (hcp) (Å)	5.182 ¹	5.183	5.149	5.149	5.186	5.215	5.168
E _{coh} (eV/atom)	-6.32 ²	-6.250	-6.250	-6.250	-6.017	-6.469	-6.635
C ₁₁ (hcp, GPa)	155 ³	160	146	155	196	165	147
C ₁₂ (hcp, GPa)	67 ³	76	70	67	88	65	69
C ₄₄ (hcp, GPa)	36 ³	36	32	36	47	48	44
C ₁₃ (hcp, GPa)	65 ³	70	65	65	81	63	74
C ₃₃ (hcp, GPa)	172 ³	174.7	164.8	173	212	180	168
E _f ^V (unrelaxed) (hcp, eV)	2.077 ⁴	1.817	1.780	1.830	1.550	2.310	1.762
Octahedral interstitial (T=0)	2.84 ⁵	4.13	2.81	8.01	3.23	3.51	2.88
Basal octahedral interstitial (T=0)	2.88 ⁵	3.98	2.63	9.10	3.02	2.87	2.90
Basal crowdion interstitial (T=0)	2.95 ⁵	3.82	2.56	8.50	3.25	3.35	2.91
I ₂ basal stacking fault defect energy (meV/Å ²)	12.5 ⁹	3.3	4.4	1.7	6.3	6.8	12.4
Prism stacking fault defect energy (meV/Å ²)	9.1 ⁹	unstable	10.1	unstable	unstable	23.3	10.9
a (fcc) (Å)	4.53 ⁴	4.571	4.543	4.553	4.557	4.545	4.538
ΔE _{hcp→fcc} (eV/atom)	0.032 ⁴	0.013	0.018	0.007	0.028	0.030	0.054
a (bcc) (Å)	3.57 ⁴	3.589	3.568	3.644	3.592	3.562	3.576
ΔE _{hcp→bcc} (eV/atom)	0.071 ⁴	0.030	0.053	0.111	0.024	0.052	0.103
C ₁₁ (bcc, GPa)	82 ⁴	119	111	56	114	96	50
C ₁₂ (bcc, GPa)	93 ⁴	119	117	118	98	109	94
C ₄₄ (bcc, GPa)	29 ⁴	83	60	113	63	42	50
T _{α→β} (K)	1136 ⁶	2054 > T _m	1211 >T _m	1251	588	1233	1385
ΔH _{α→β} (eV/atom)	0.040 ⁶	0.054	0.041	0.037	0.019	0.039	0.058
ΔV _{α→β} /V _α (%)	-0.4 ⁷	+1.3	+1.9	+4.9	-1.5	-0.8	+0.9
T _m (hcp, K)		1778	1045	1765	1555	1913	1369
T _m (bcc, K)	2128 ⁶	1681	950	1887	1692	2109	1358
T _m (fcc, K)		1750	988	1739	unstable	unstable	unstable
d (liquid, T=2128 K) (atom/nm ³)	39.56 ⁸	37.19	37.26	31.39	38.55	40.08	39.65
ΔH _m (eV/atom)	0.151 ⁶	0.161	0.108	0.103	0.167	0.179	0.078
ΔV _m /V _s (%)	3.9 ⁶	4.5	3.7	3.4	4.9	2.6	1.2

Temperature dependence of axial ratio c/a

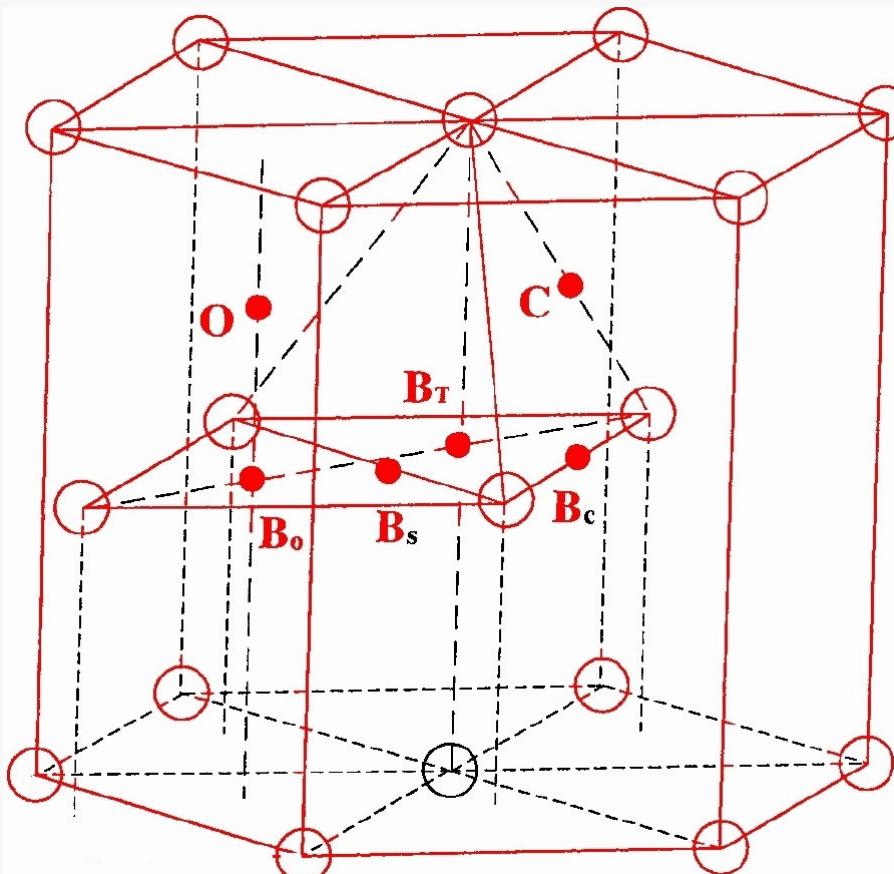


Diffusion of point defects



Possible configurations of SIA in HCP lattice

C.H. Woo, Hanchen Huang and W.J. Zhu, Appl. Phys. A76 (2003) 101



- Octahedral (**O**)
- Basal tetrahedral (**B_T**)
- Basal octahedral (**B_O**)
- Basal crowdion (**B_c**)
- Basal split (**B_s**)
- Non-basal crowdion (**C**)
- c-dumbbell (**D_c**)

Configuration	B _C	B _S	B _O	B _T	O	C
Ackland (eV)	3.71	3.72	3.93	3.98	4.08	3.93
Pasianot (eV)	3.75	3.76	3.88	4.05	4.05	4.03

Stable Unstable Metastable Unstable Unstable Unstable

Point defect diffusivities

a) Via calculation of atomic displacements

$$D_a = f_d C_d D_d \quad f_v = \begin{cases} 0.653, & \text{sc} \\ 0.782, & \text{fcc} \end{cases}$$

$$D_d = D_a / f_d C_d$$

$$D_a = \langle \Delta r^2 \rangle / 6t$$

b) Direct tracing of defect diffusion

$$t_j = \Delta t \cdot j \quad R^2 = \sum_j (r_j - r_{j-1})^2$$

$$D \rightarrow R^2 / 6N\Delta t$$

$$D_c = \langle (z_j - z_{j-1})^2 \rangle / 2\Delta t$$

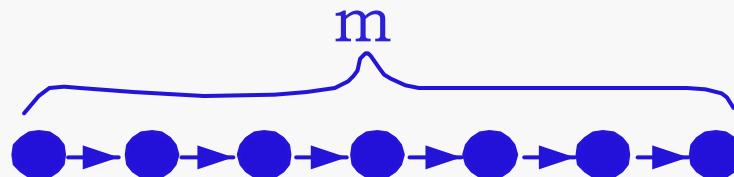
Why f_i can be very small?

1- α space jumps: dumbbell SIA motion

After k jumps mean-squared displacement

of SIA $r_{\text{int}}^2 \rightarrow k \cdot a^2$

and atoms $r_{\text{atoms}}^2 \rightarrow k \cdot a^2$ $D_{\text{atoms}} \rightarrow C_{\text{int}} D_{\text{int}}$

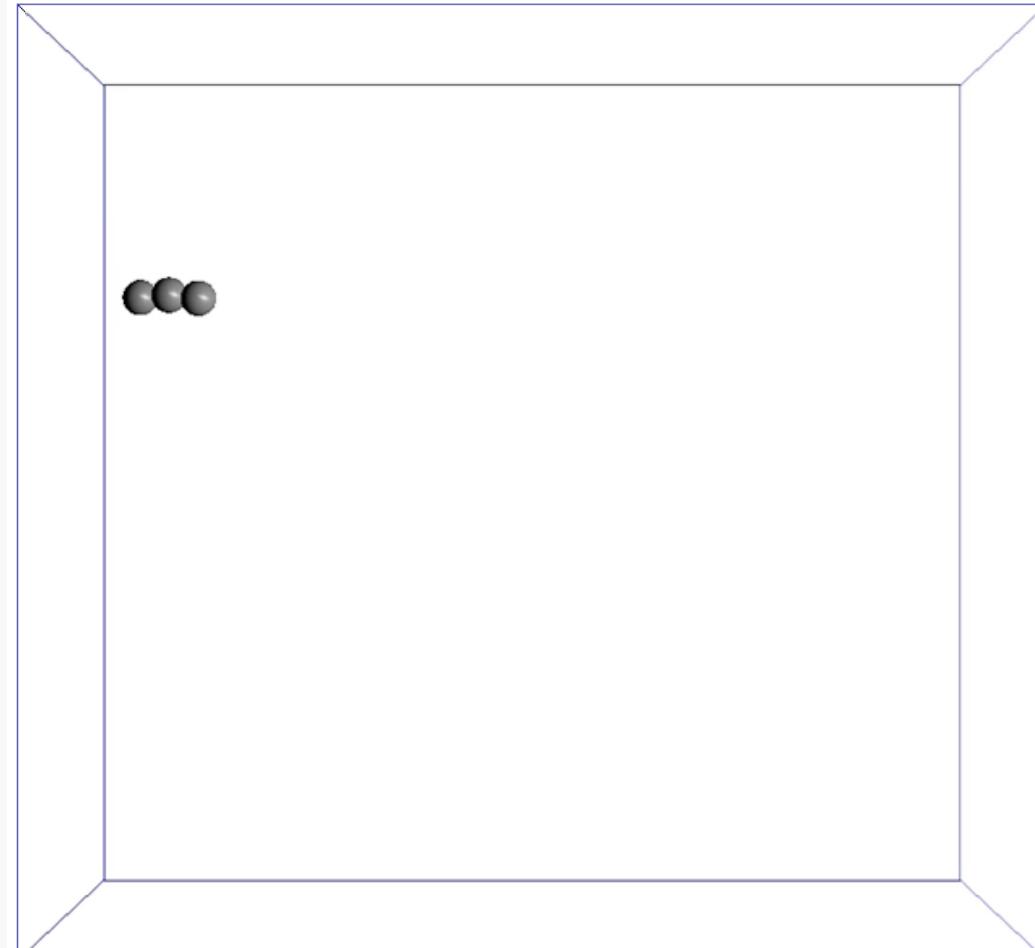
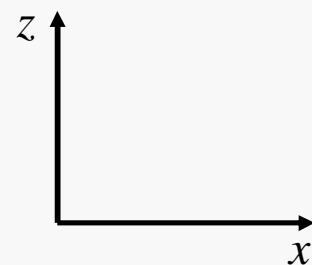


m - α space jumps: crowdion motion

$$r_{\text{int}}^2 \rightarrow k \cdot (ma)^2$$

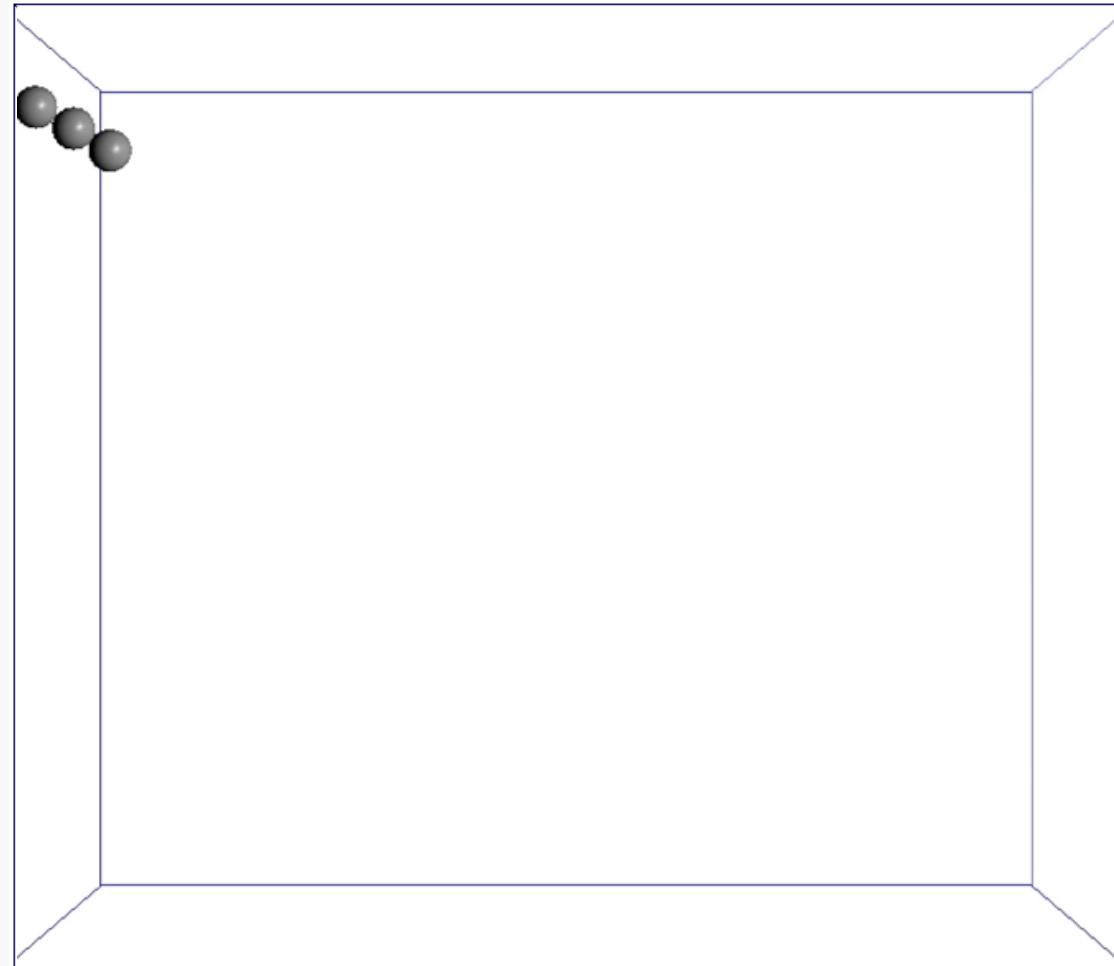
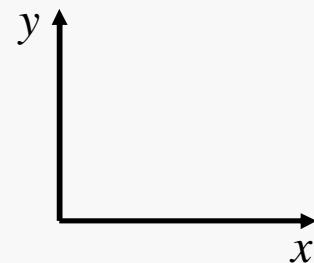
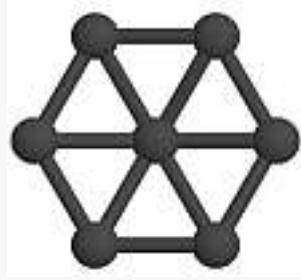
$$r_{\text{atoms}}^2 \rightarrow k \cdot ma^2 \quad D_{\text{atoms}} \rightarrow \frac{1}{m} C_{\text{int}} D_{\text{int}}$$

Crowdion motion of SIA



movie

Crowdion motion of SIA



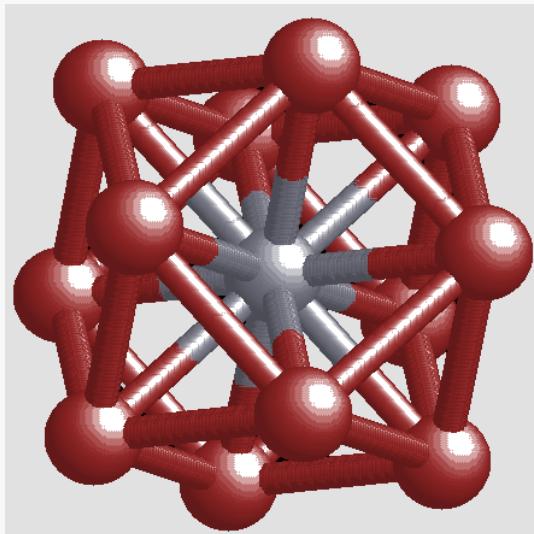
movie

Interstitial self-diffusion?

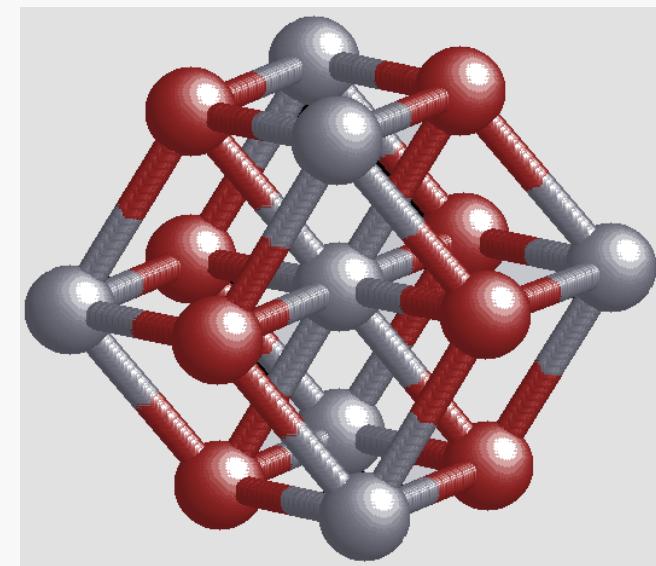
Phase	Defect	E_f at T=1000 K	E_m	E_f+E_m	E_D (experiment)
hcp	Vacancy	2.38	1.23	3.61	3.17
	Interstitial	3.17	0.11	3.28	
bcc	Vacancy	2.00	0.44	2.44	2.04
	Interstitial	2.04	0.11	2.15	

Martensitic Phase Transformation in Zr

$\alpha\text{-Zr} \rightarrow \beta\text{-Zr}$ at $T = 1136$ K

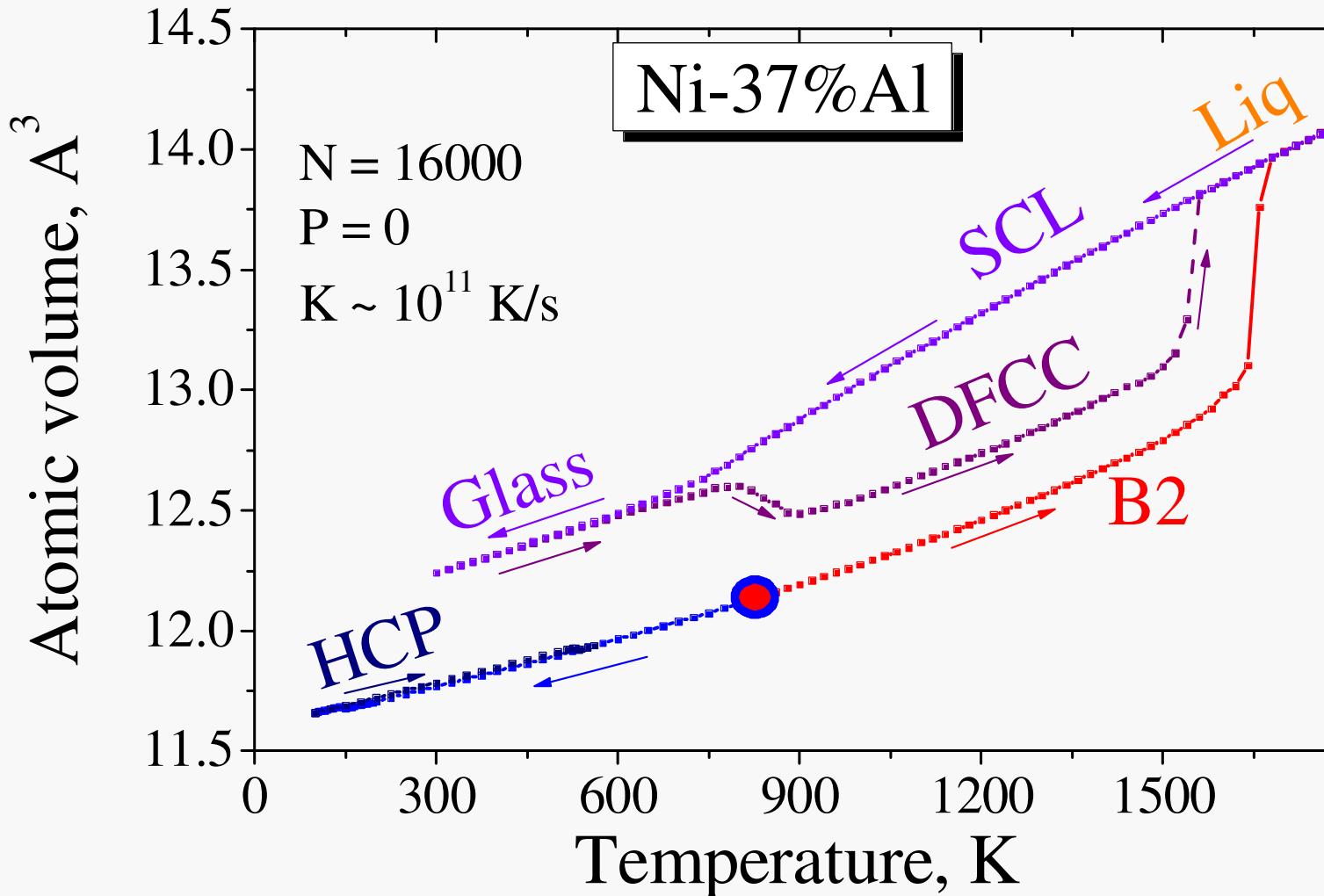


HCP

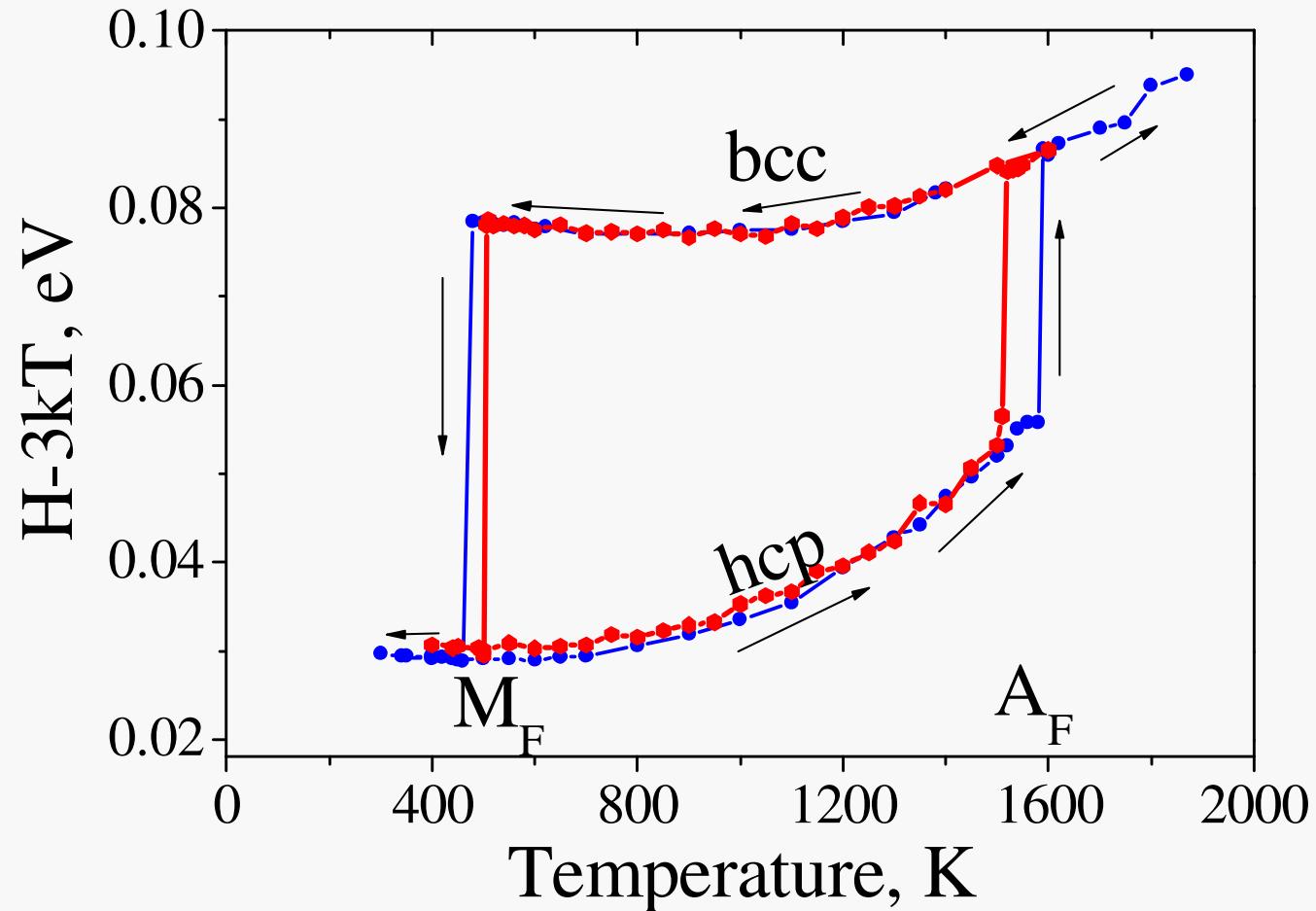


BCC

“Kinetic Phase Diagram”



Enthalpy at Reversible Temperature-Controlled MT



- *The 1-st order phase transformations: $A \rightarrow M \rightarrow A$*

Thermodynamics of MT and temperature T_0

$$F = H - TS$$

$$S = -\left. \frac{\partial F}{\partial T} \right|_{P=0} \quad \frac{d}{dT} \left(\frac{F}{T} \right) = -\frac{H}{T^2}$$

$$\frac{\Delta F(T)}{T} = \frac{\Delta F(T_1)}{T_1} - \int_{T_1}^T [\Delta H(\tau)/\tau^2] d\tau$$

$$\Delta S_{AM} = ?$$

Entropy of harmonic system

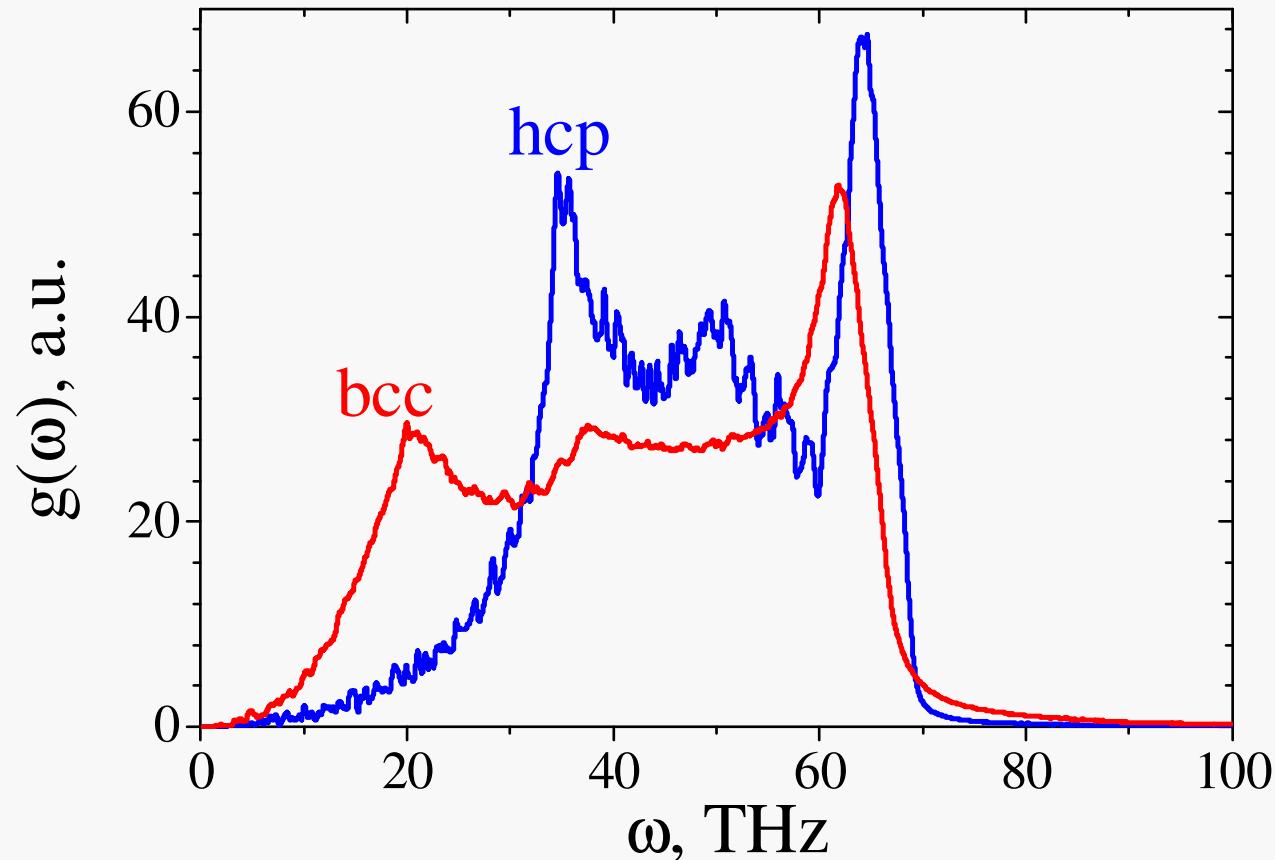
$$S_{har} = -k_B \sum_j \ln(\hbar\omega_j / k_B T) + S_0$$

$$\Delta S_{AM} = - \int_0^{\infty} \ln(\omega) [g_A(\omega) - g_M(\omega)] d\omega = - \ln \frac{\bar{\omega}_A}{\bar{\omega}_M}$$

$$A_{VV}(t) = \int_0^{\infty} V(\tau) V(\tau + t) d\tau$$

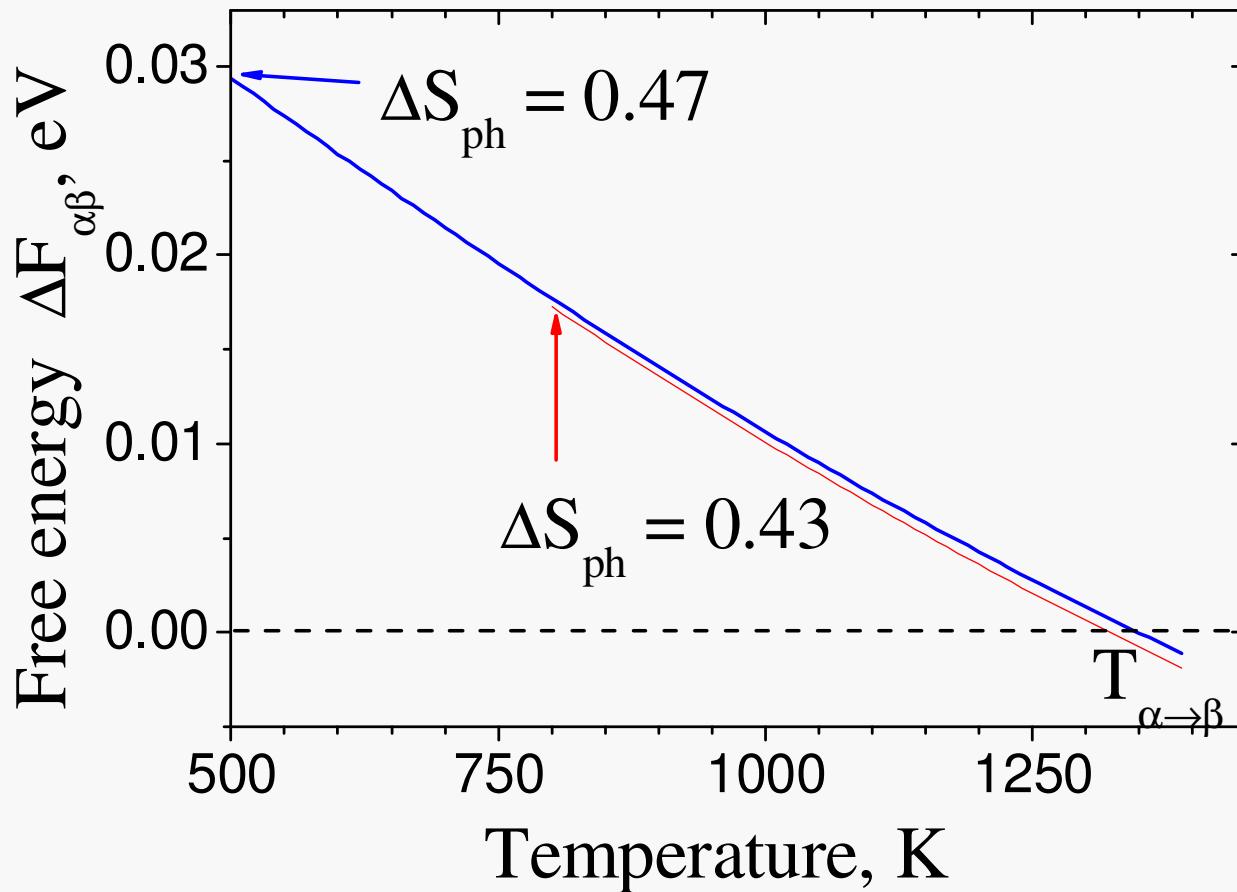
$$g(\omega) = \frac{1}{2\pi} \int_0^{\infty} e^{-\omega t} A_{VV}(t) dt$$

Spectral densities in martensite and austenite phases



- $\Delta S_{\alpha\beta} = 0.45k$

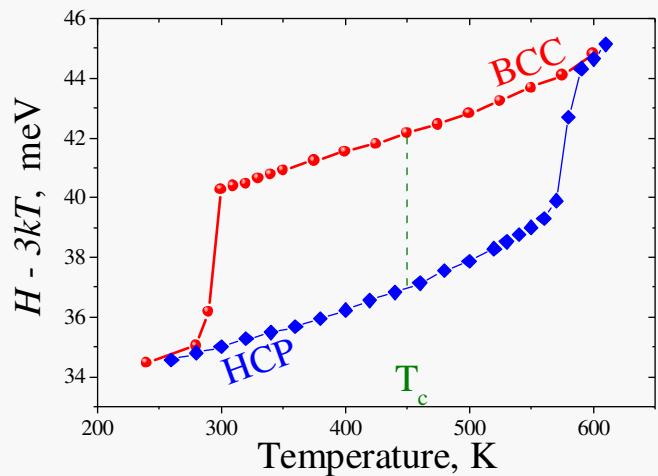
Free energy difference



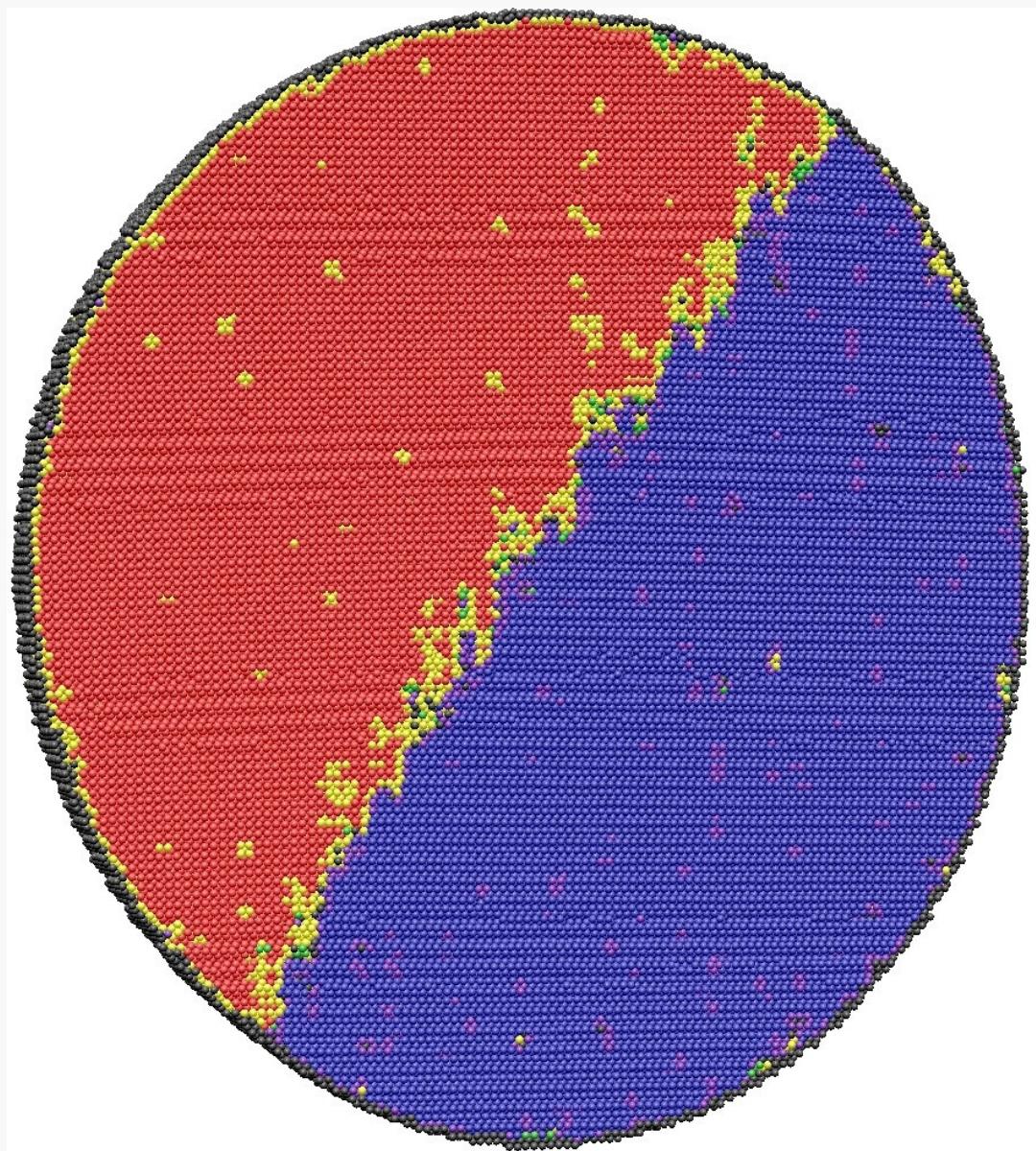
- $T_0 \approx 1340 K$

Phase coexistence, T_c

Ni_7Al_5
 $T = 450\text{K}$, $N = 1809648$

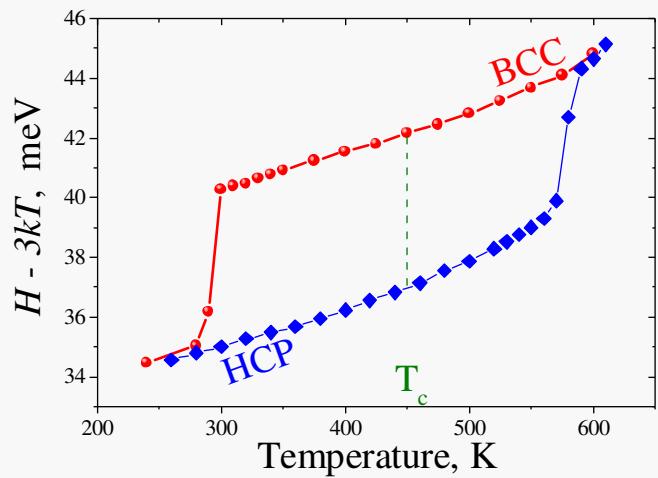


Perfect FCC+HCP
Distorted FCC+HCP
Perfect BCC
Distorted BCC
Perf. & Dist. ICO
Unclassified

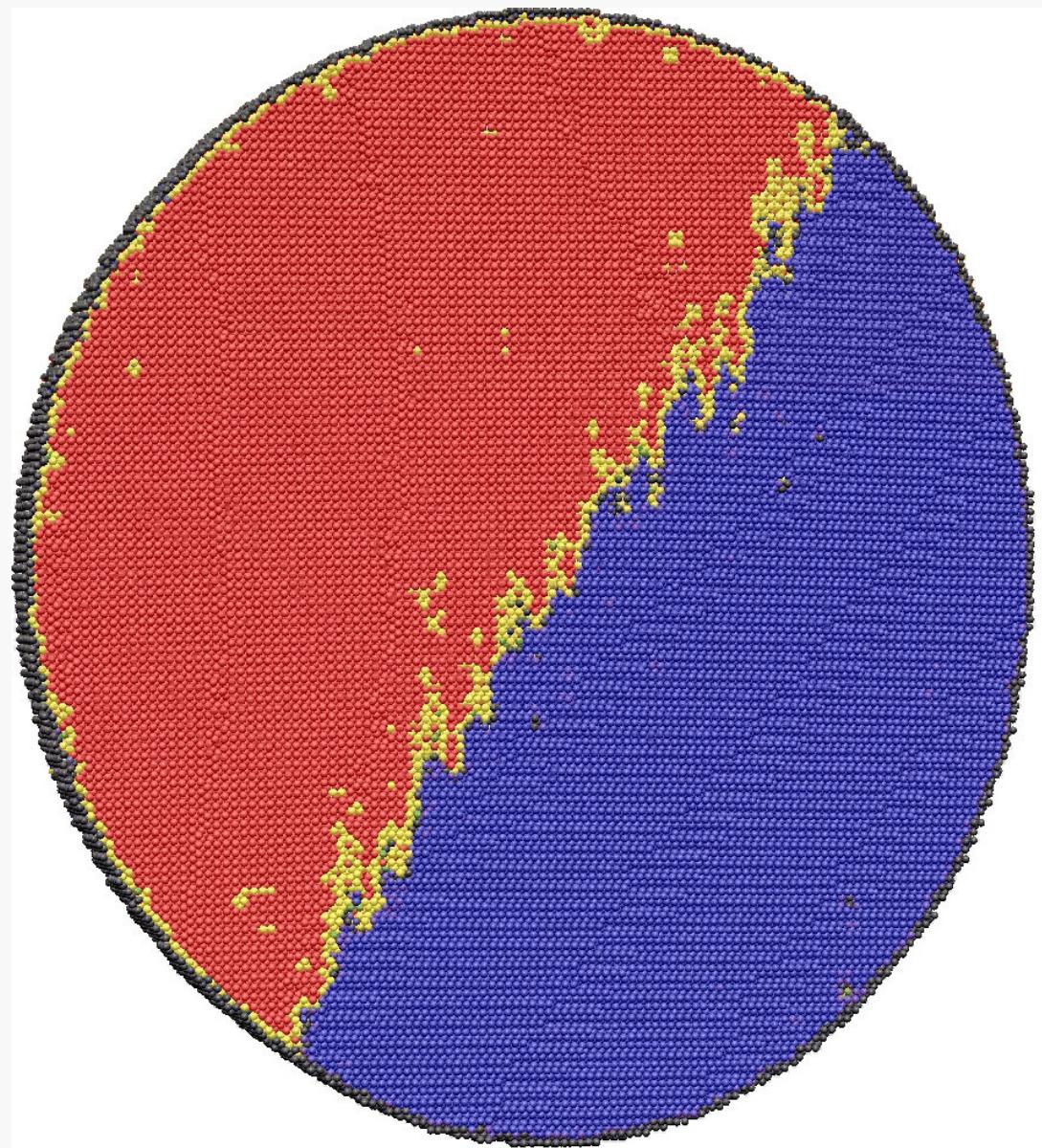


Phase coexistence, T_c

Ni_7Al_5
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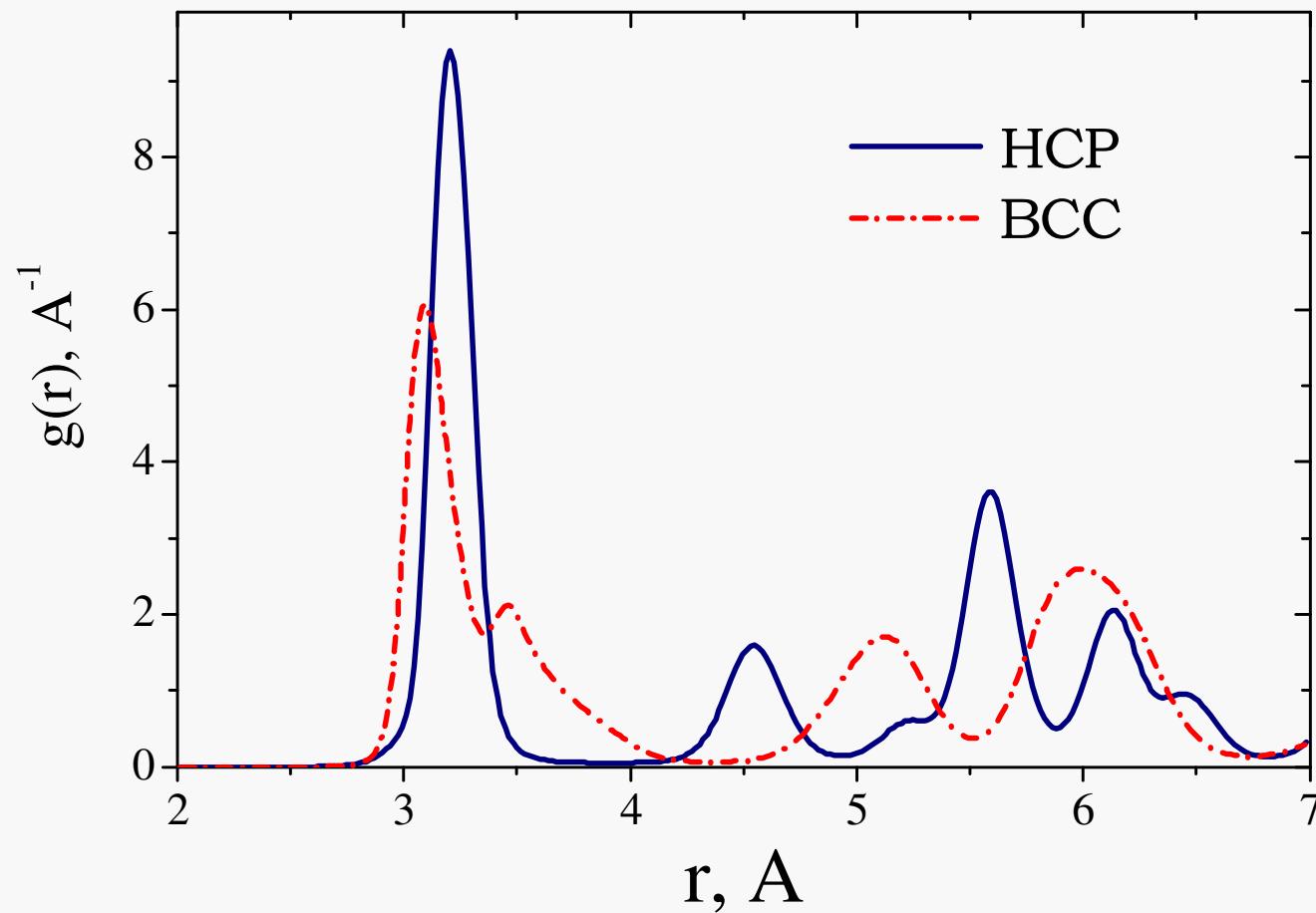


Perfect FCC+HCP
Distorted FCC+HCP
Perfect BCC
Distorted BCC
Perf. & Dist. ICO
Unclassified



Radial Distribution Function

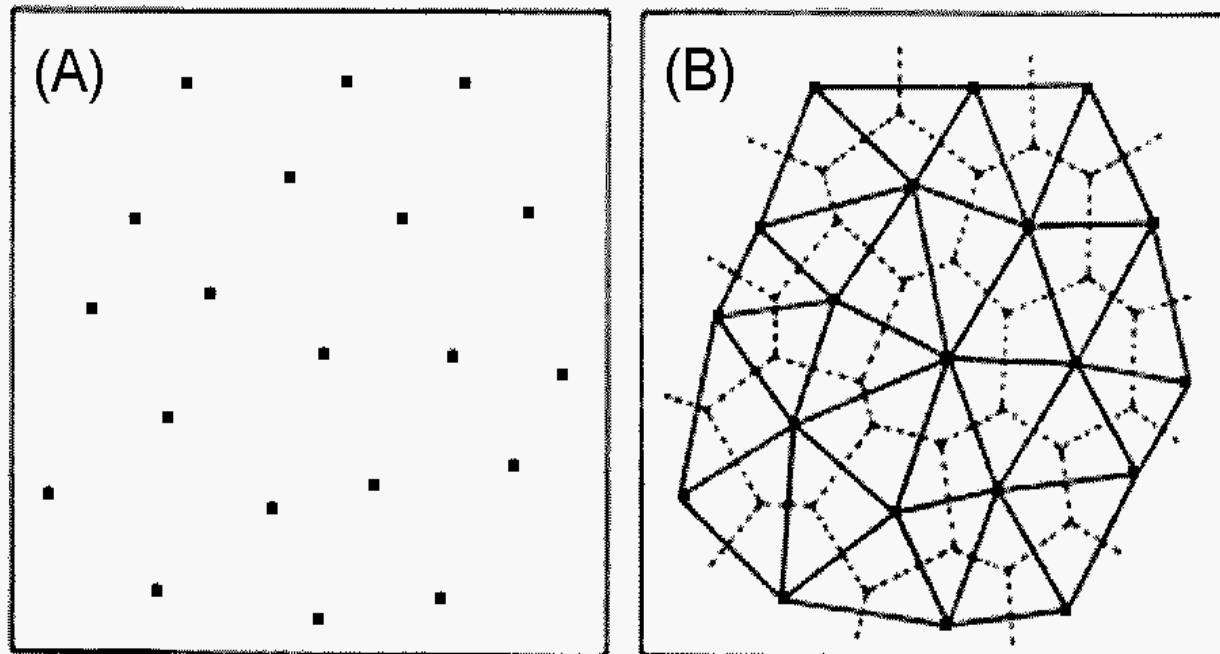
$$g(r) = \frac{V}{4\pi r^2 N^2} \left\langle \sum_i \sum_{j \neq i} \delta(r - r_{ij}) \right\rangle$$



Local Order Characterization

1-st step: Voronoy tessellation

S. Nosé and F. Yonezawa, J. Chem. Phys. 84 (1979) 1803



Definition of neighbors: *Voronoy polyhedra share a common face*

Local Order Characterization

2-nd step: Common Neighbors Analysis (CNA):

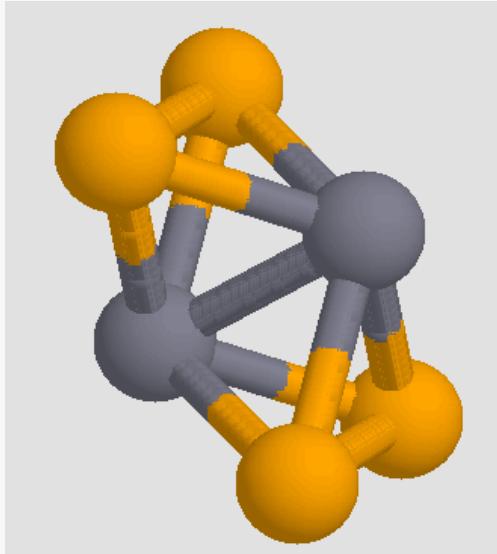
H. Jonsson, H. C. Andersen, *Phys. Rev. Lett.* 60, (1988) 2295

Bond index $lijk$:

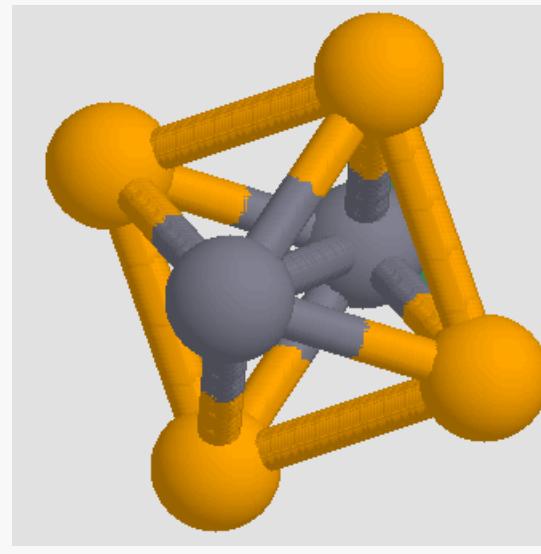
i is the number of CNs.

j is the number of common bonds between the CNs.

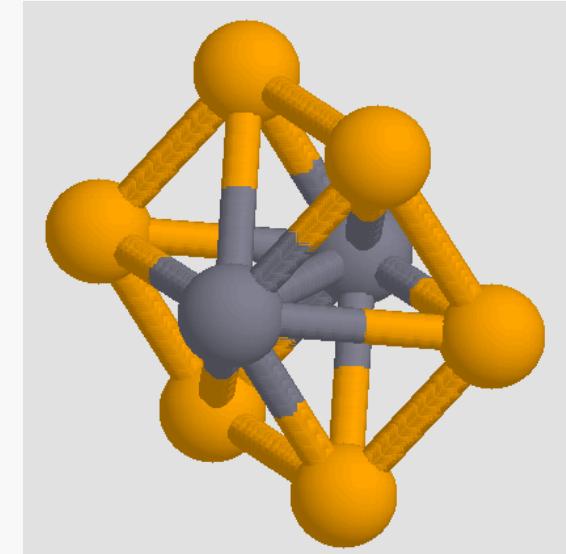
k is the longest continuous chain formed by bonds between CNs.



$$\text{FCC} = 12 \times 1421$$



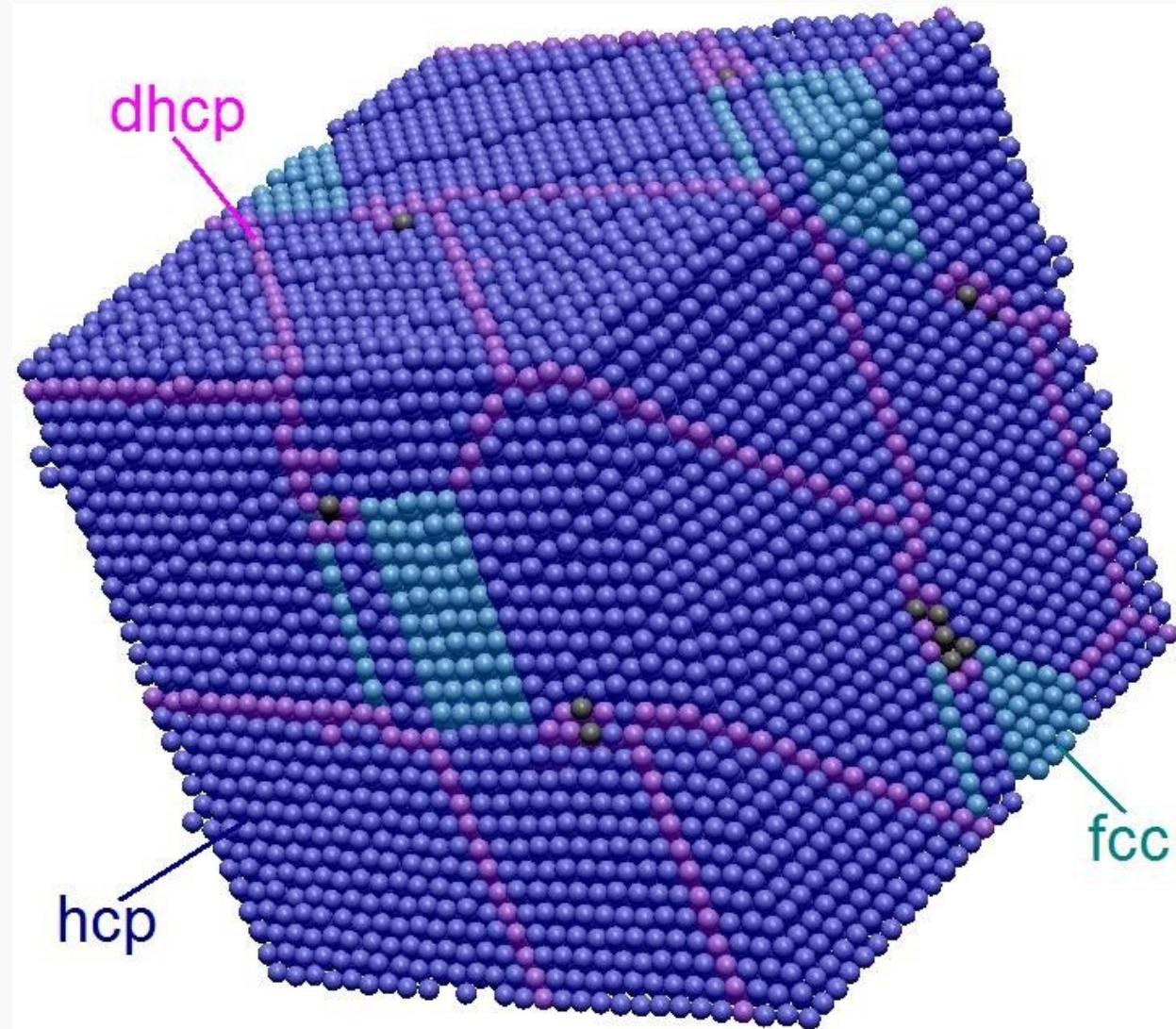
$$\text{BCC} = 8 \times 1444 + 6 \times 1666$$



Structure of martensite state after transformation (PBC)

T = 1000K
N = 43904

Perfect HCP
Perfect FCC
Distorted FCC + HCP
Perfect BCC
Distorted BCC
Perf. & Dist. ICO
Unclassified



Heterogeneous transformation $\beta \rightarrow \alpha$

$T = 520K$

$N = 204300$

Perfect HCP

Perfect FCC

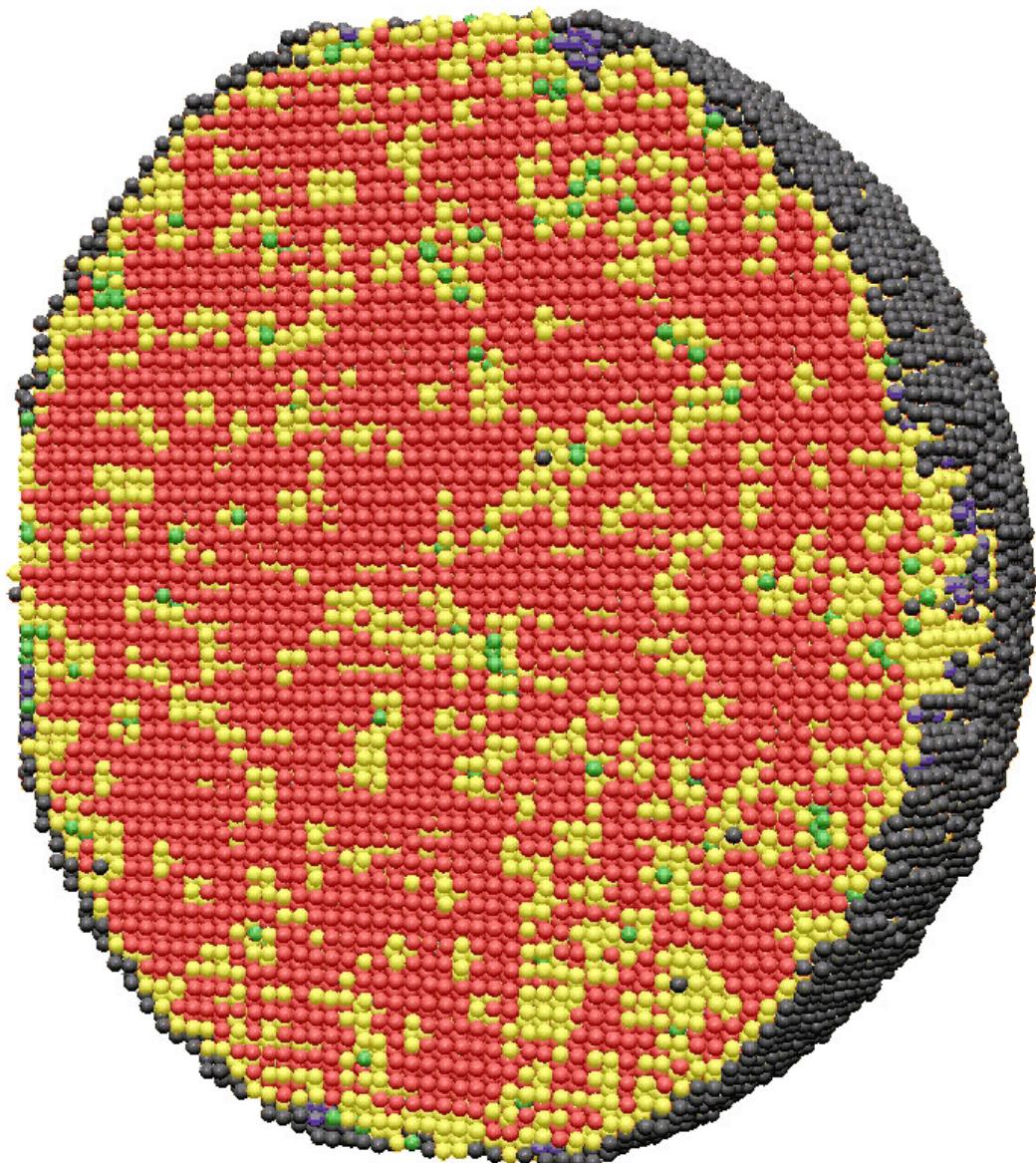
Distorted FCC + HCP

Perfect BCC

Distorted BCC

Perf. & Dist. ICO

Unclassified



Reverse transformation $\alpha \rightarrow \beta$

$T = 1560K$

$N = 204300$

Perfect HCP

Perfect FCC

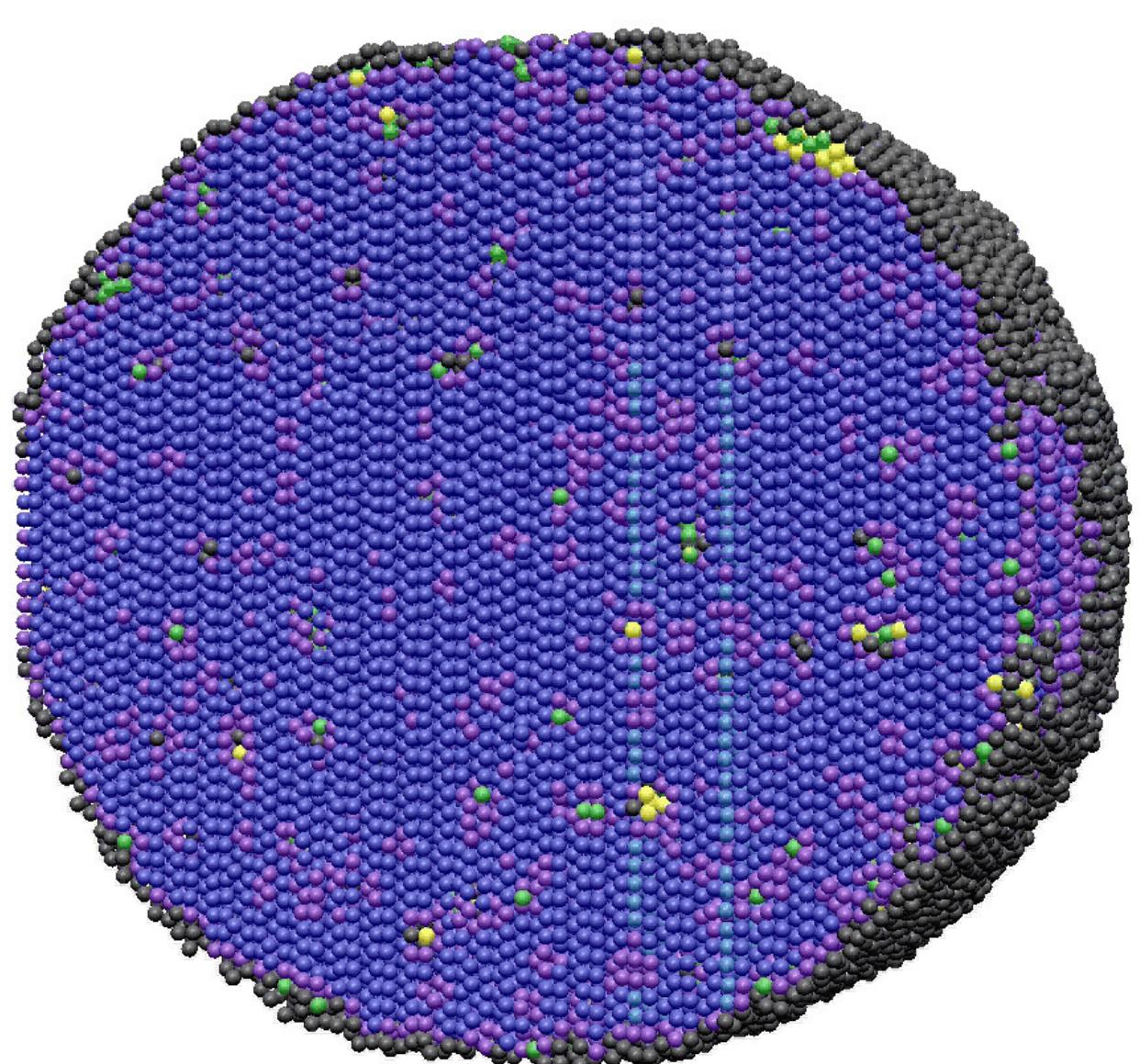
Distorted FCC + HCP

Perfect BCC

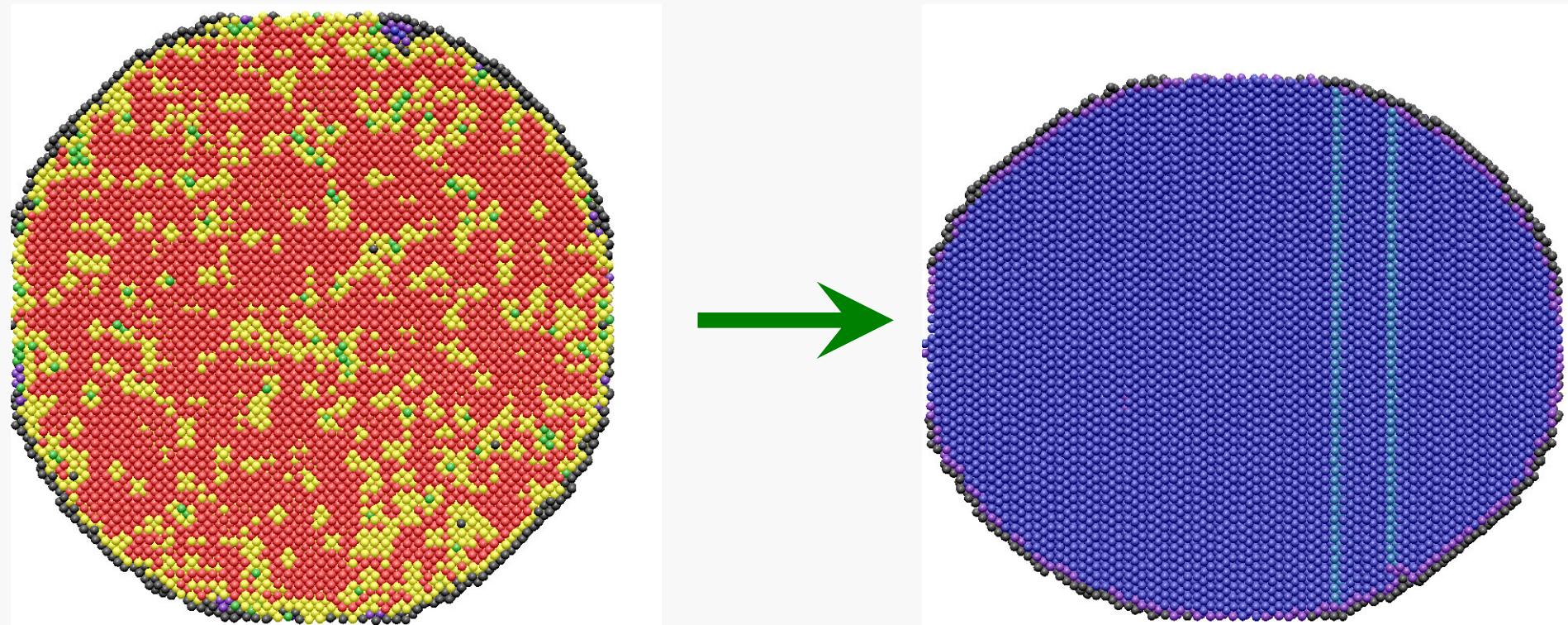
Distorted BCC

Perf. & Dist. ICO

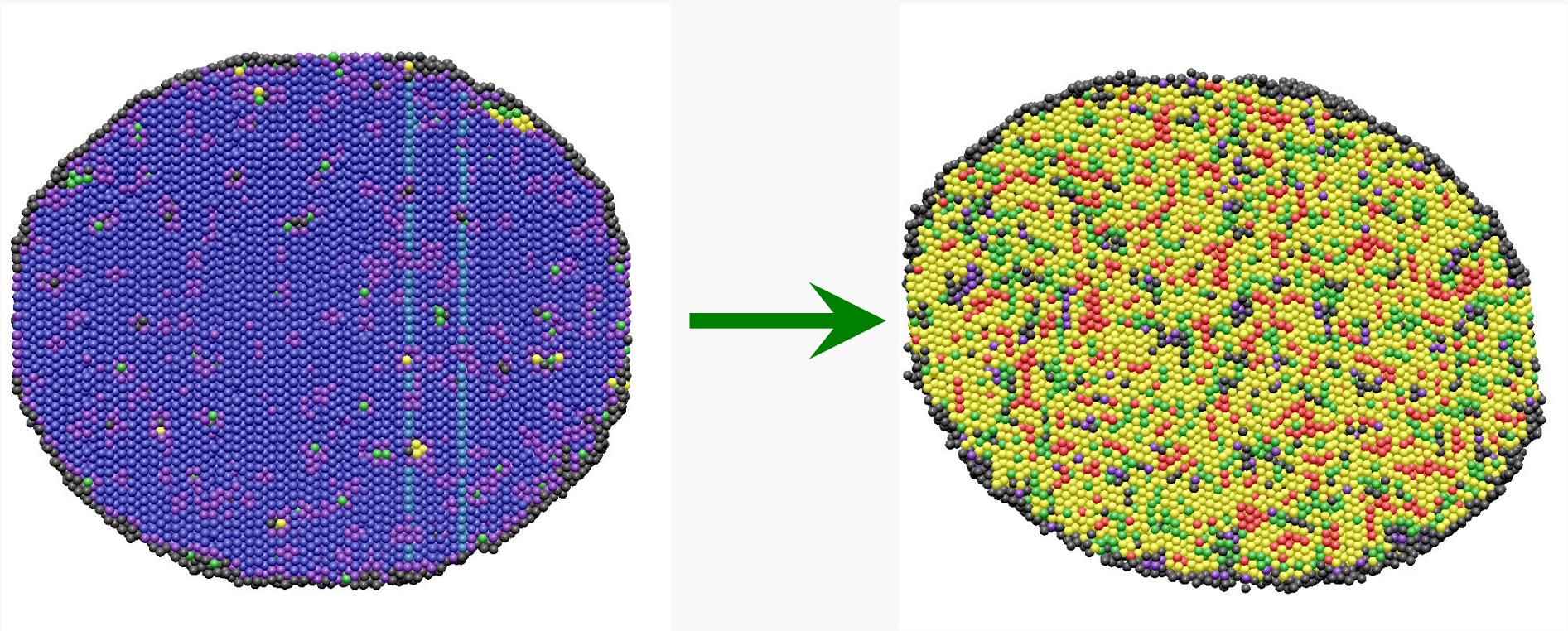
Unclassified



Initial and Final States at Transformation $\beta \rightarrow \alpha$



Initial and Final States at Transformation $\alpha \rightarrow \beta$



$\beta \rightarrow \alpha$ heterogeneous MT in polycrystalline Zr

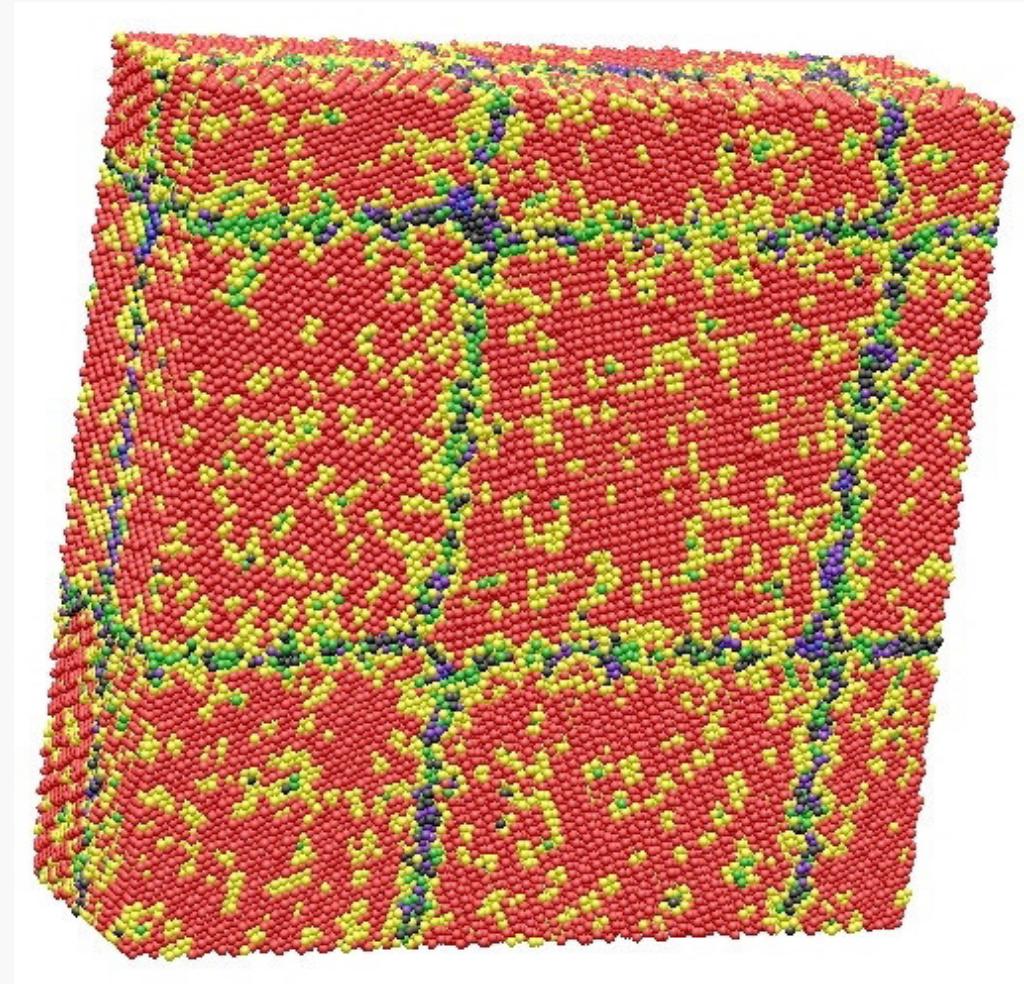
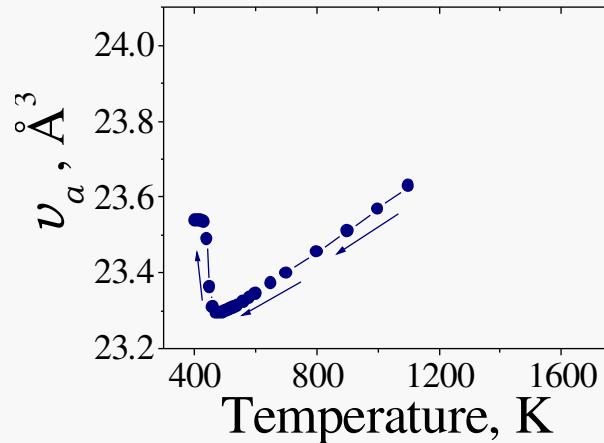
$N = 2\,050\,000$

Perfect FCC + HCP
Distorted FCC + HCP
Perfect BCC
Distorted BCC
Perf. & Dist. ICO
Unclassified



$T = 800$ K

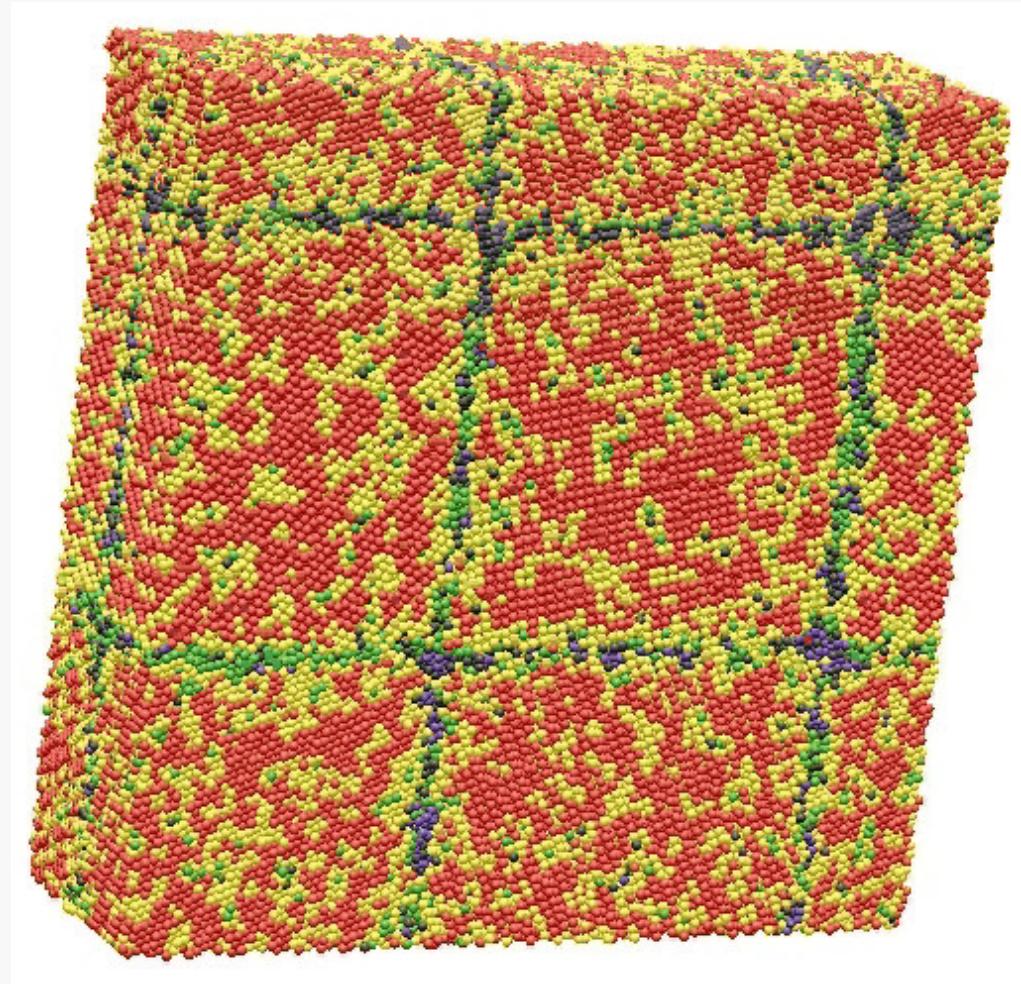
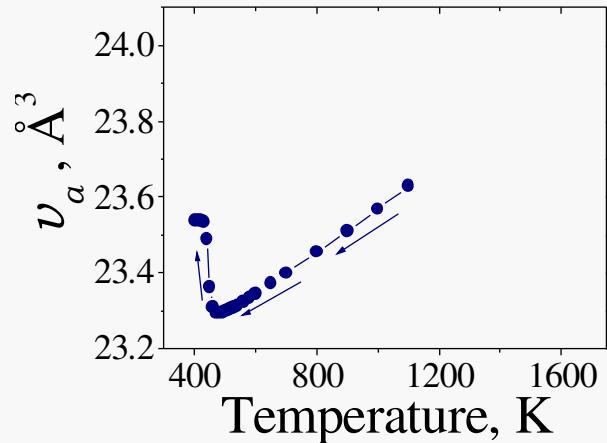
$\beta \rightarrow \alpha$ heterogeneous MT in polycrystalline Zr



Perfect FCC + HCP
Distorted FCC + HCP
Perfect BCC
Distorted BCC
Perf. & Dist. ICO
Unclassified

$N = 1\,055\,276$

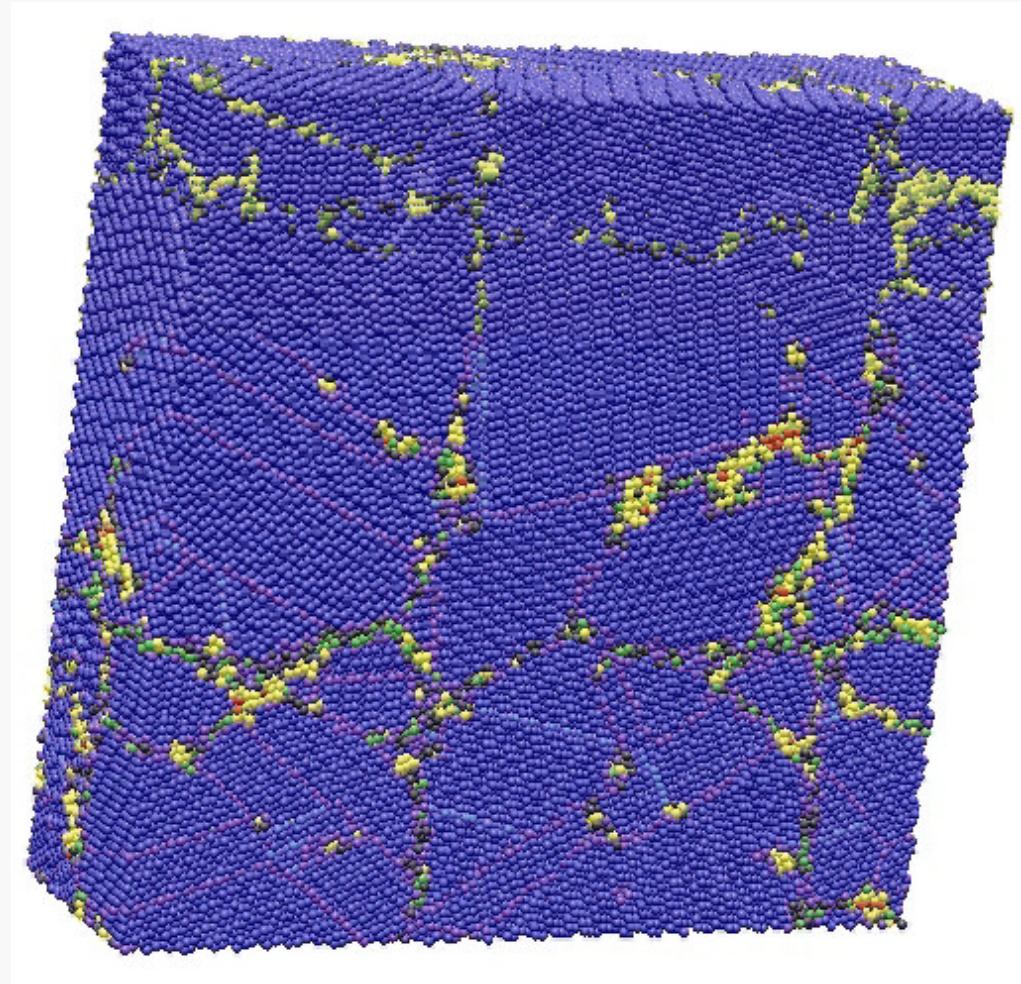
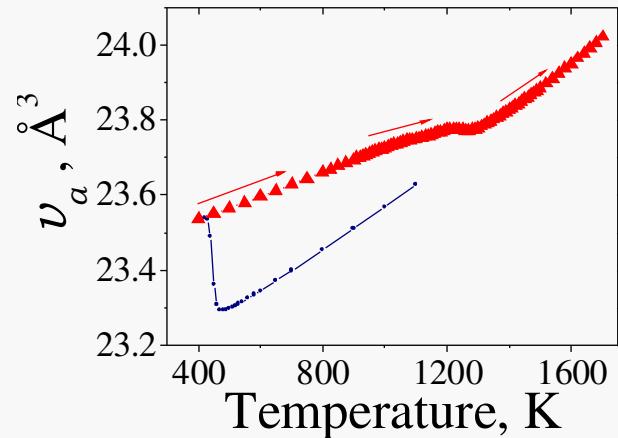
$\beta \rightarrow \alpha$ heterogeneous MT in polycrystalline Zr



Perfect FCC + HCP
Distorted FCC + HCP
Perfect BCC
Distorted BCC
Perf. & Dist. ICO
Unclassified

$N = 1\,055\,276$

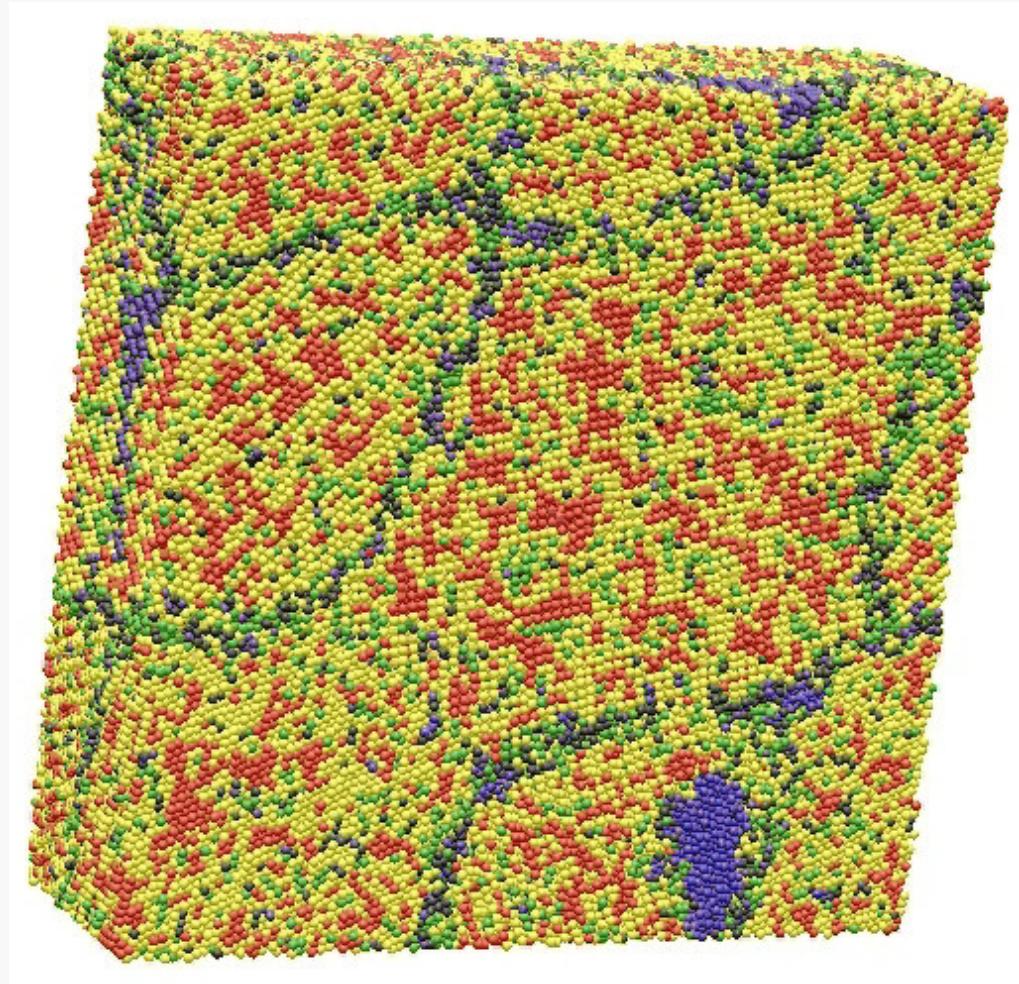
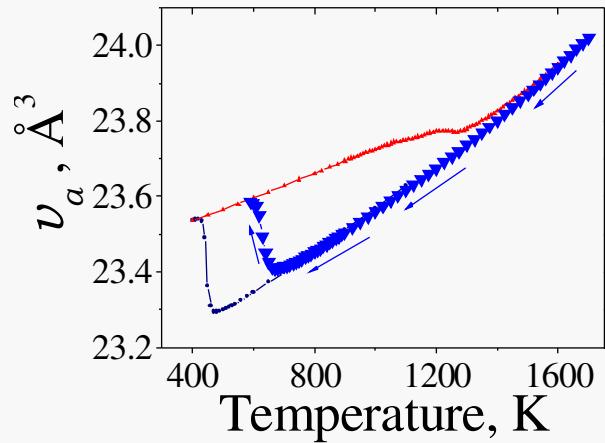
$\alpha \rightarrow \beta$ heterogeneous MT in polycrystalline Zr



Perfect FCC + HCP
Distorted FCC + HCP
Perfect BCC
Distorted BCC
Perf. & Dist. ICO
Unclassified

$N = 1\,055\,276$

2-nd cycle of $\beta \rightarrow \alpha$ heterogeneous MT in Zr



Perfect FCC + HCP
Distorted FCC + HCP
Perfect BCC
Distorted BCC
Perf. & Dist. ICO
Unclassified

$N = 1\,055\,276$

Primary damages in displacement cascades

$$N = 10^5 - 2 \cdot 10^6$$

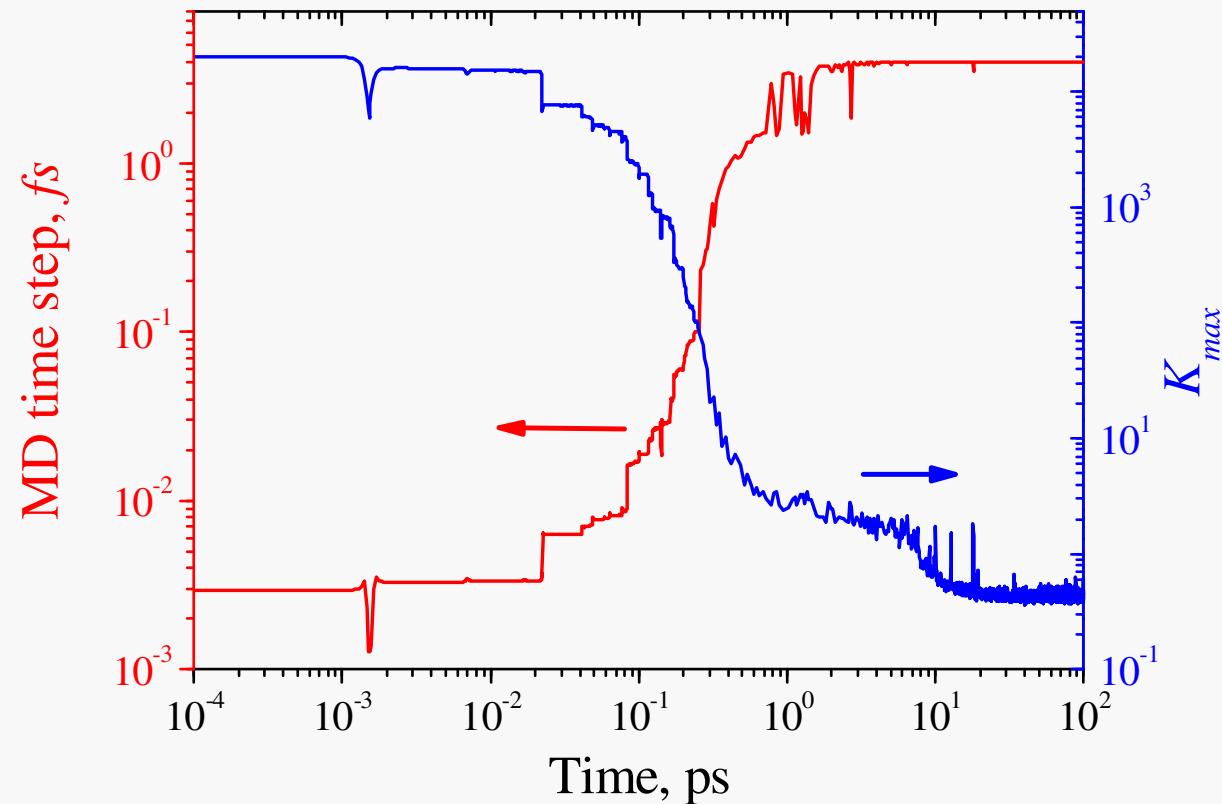
PKA energies: 0.01 – 20 keV

Temperatures: 300, 600, 900 K

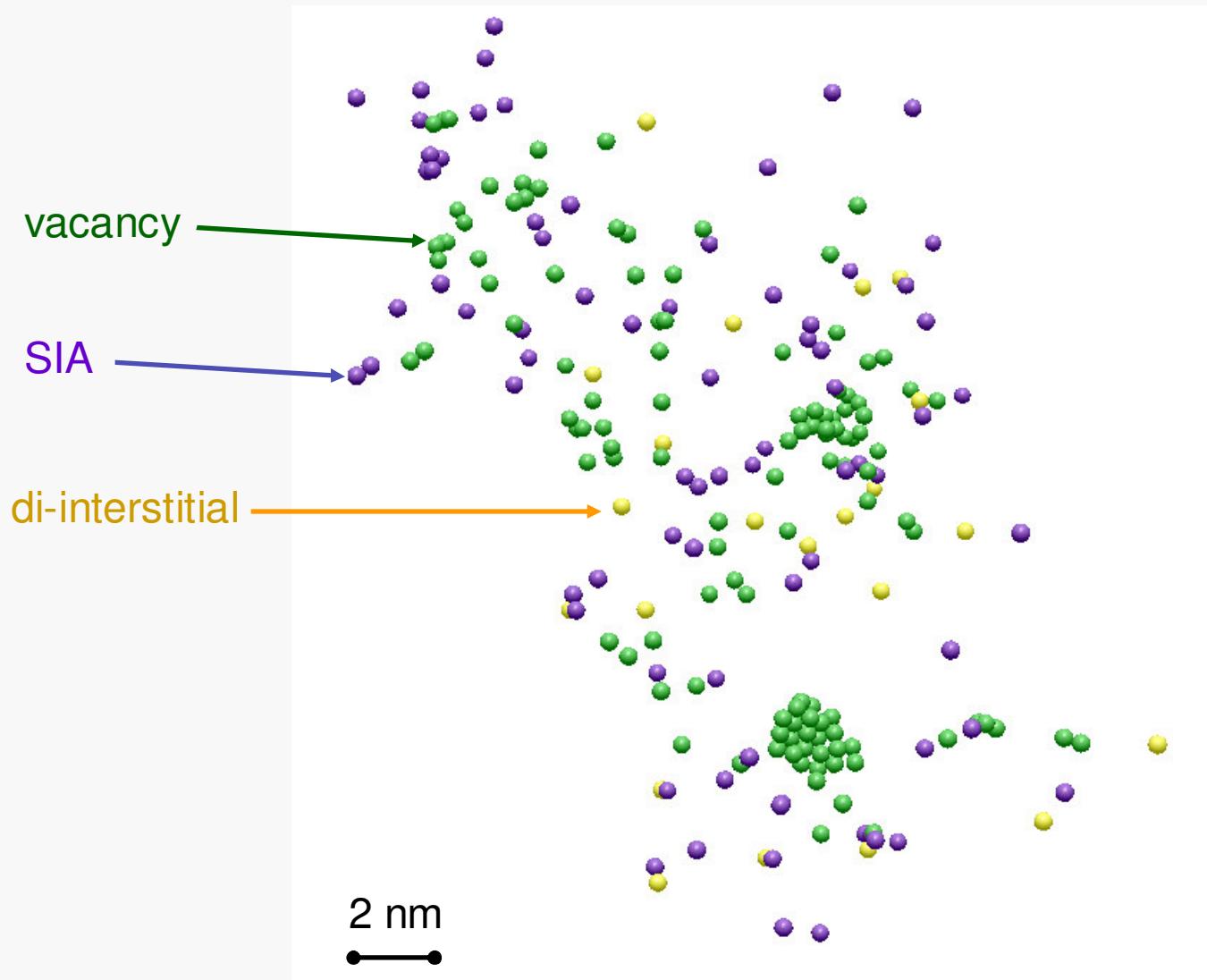
Total cascades: > 600

$$E_d \sim 24 - 20 \text{ eV} \quad (T = 300 - 900 \text{ K})$$

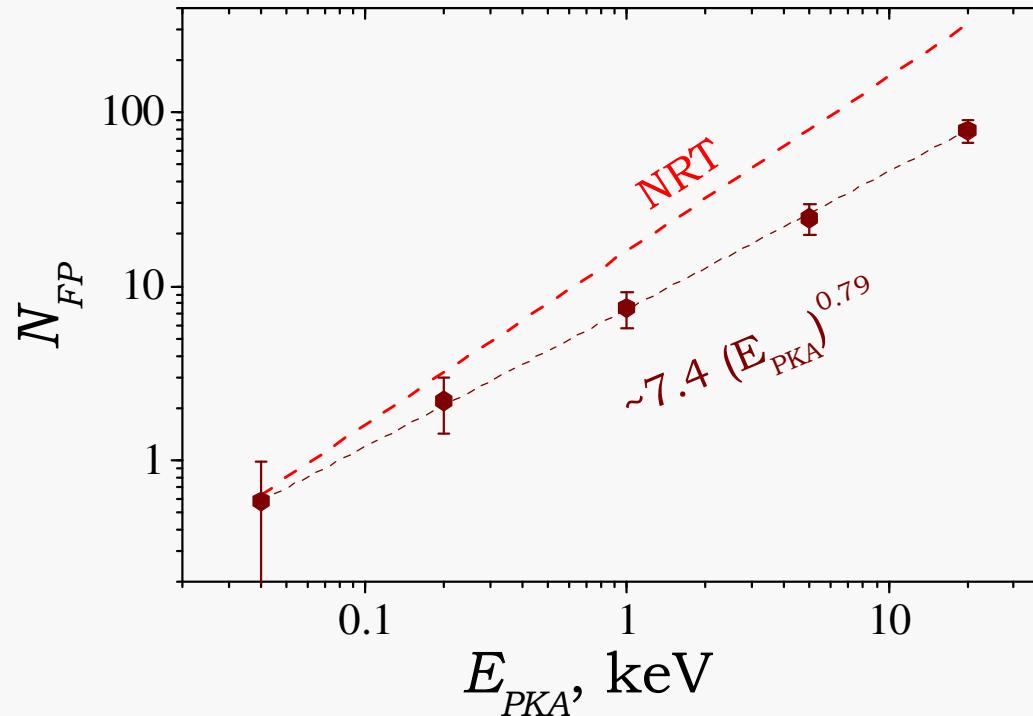
MD time step vs fastest atom energy



Point defect distribution, $E_{PKA} = 20 \text{ keV}$, $T = 300 \text{ K}$



Defect production in Zr (MA potential) at T = 300K

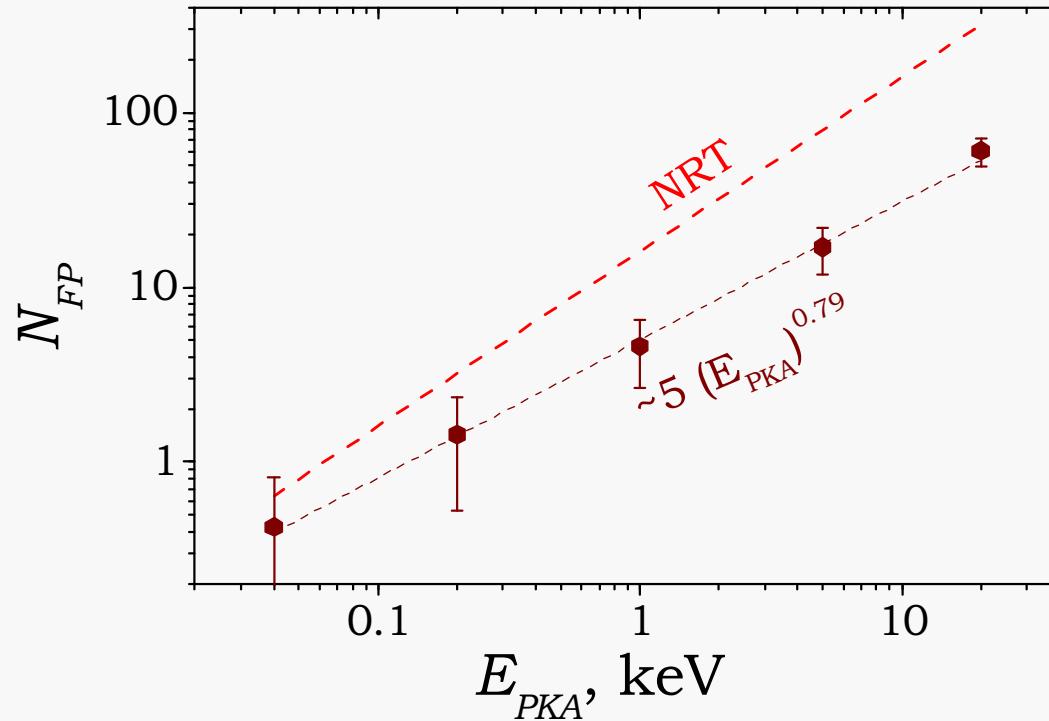


The standard Norgett-Robinson-Torrens (NRT) theory:

$$N_{NRT} = 0.8 E_d / 2E_d$$

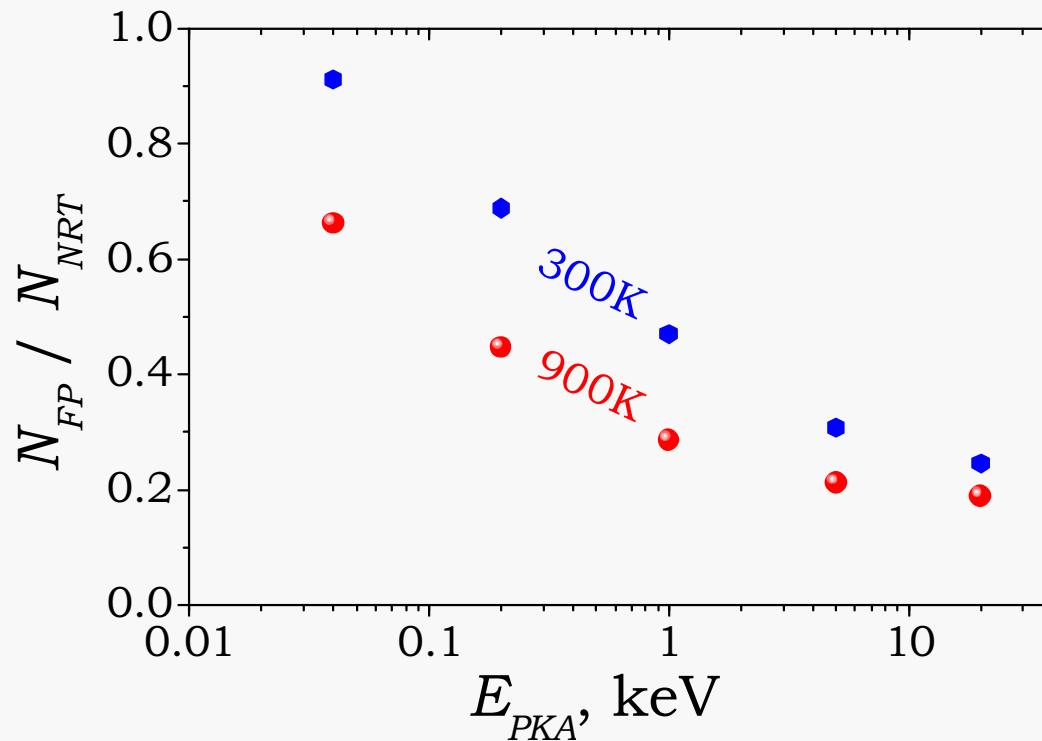
For simulated Zr (MA) we estimate threshold energy $E_d = 25$ eV

Defect production in Zr (MA potential) at T = 900K



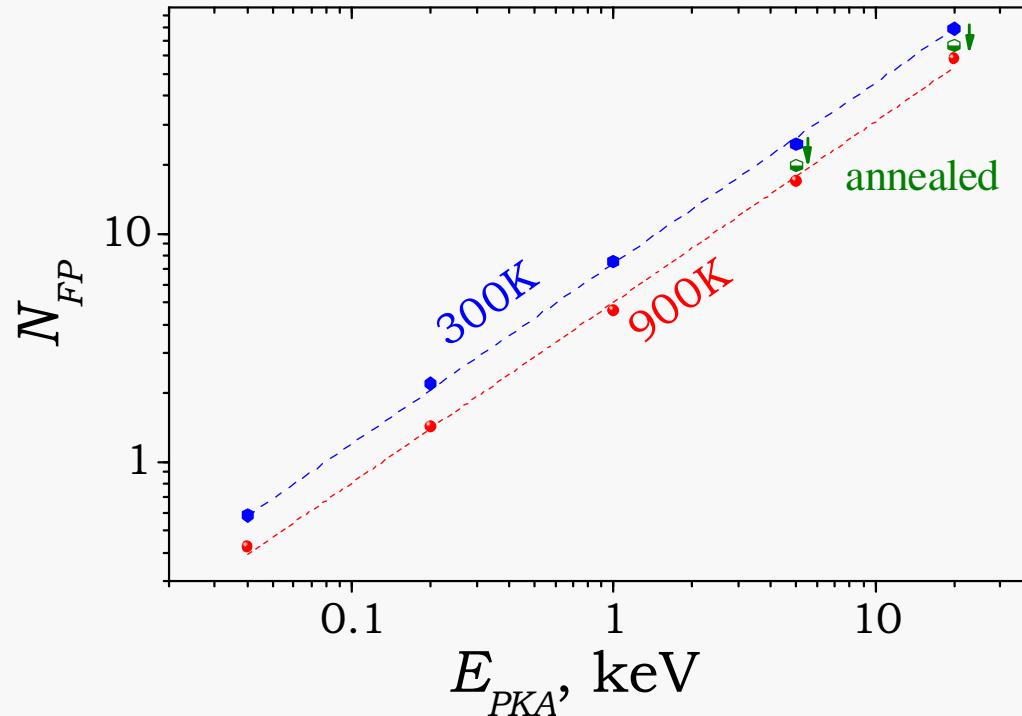
The number of the survived point defects decreases when the temperature rises.

Survived point defects fraction



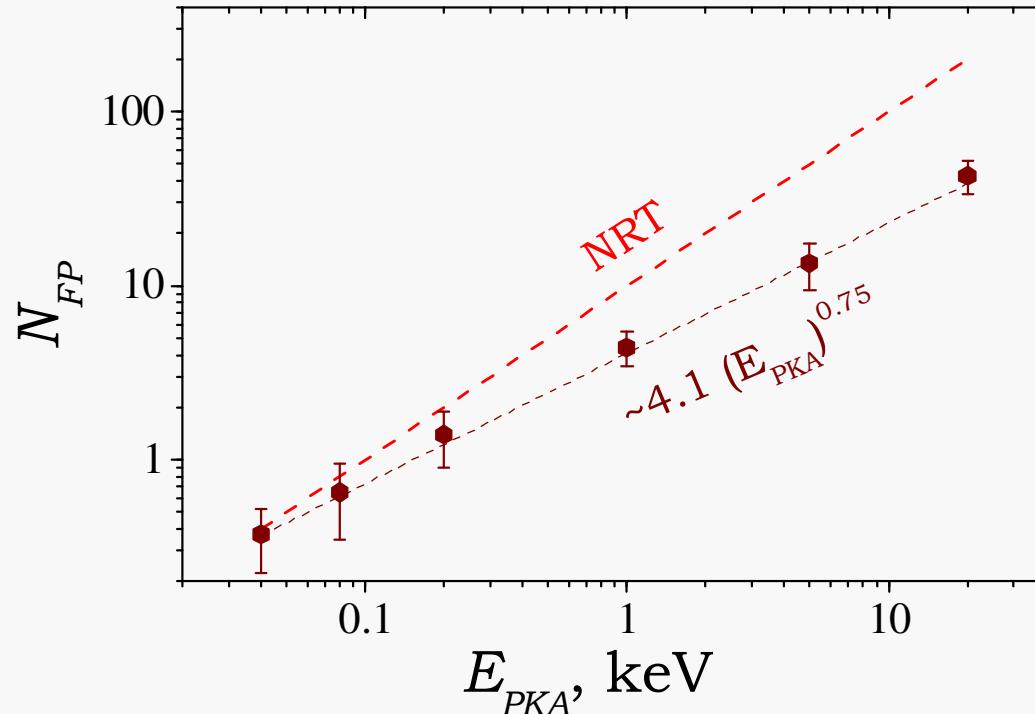
Damage production efficiency is degraded with increase cascade energy

Effect of cascade defects annealing at high temperature



Annealing of low temperature cascade defects smoothes over the temperature effect

Defect production in Zr (AWB potential) at T = 300K

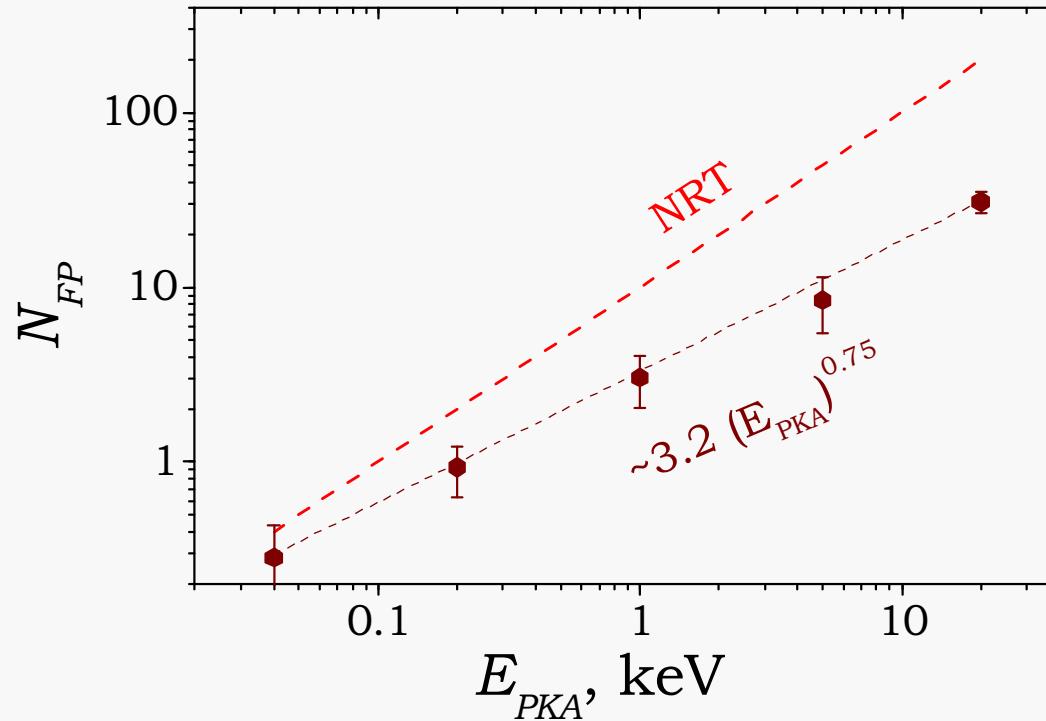


The standard Norgett-Robinson-Torrens (NRT) theory:

$$N_{NRT} = 0.8 E_D / 2E_d$$

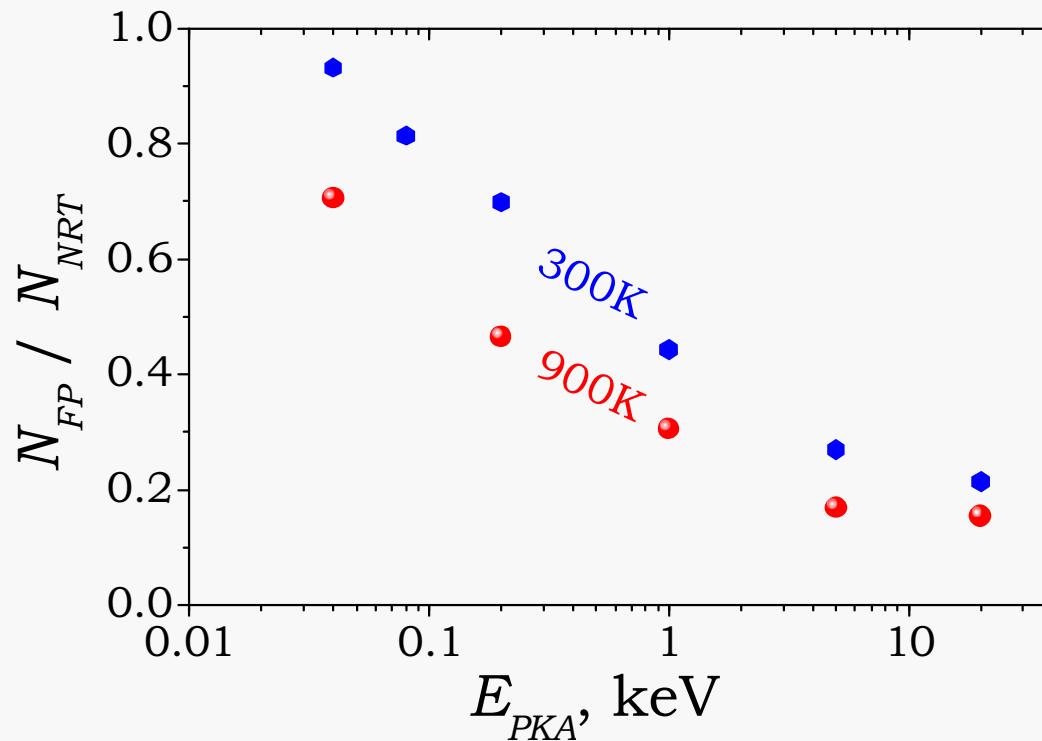
For simulated Zr (MA) we estimate threshold energy $E_d = 40$ eV

Defect production in Zr (AWB potential) at T = 900K



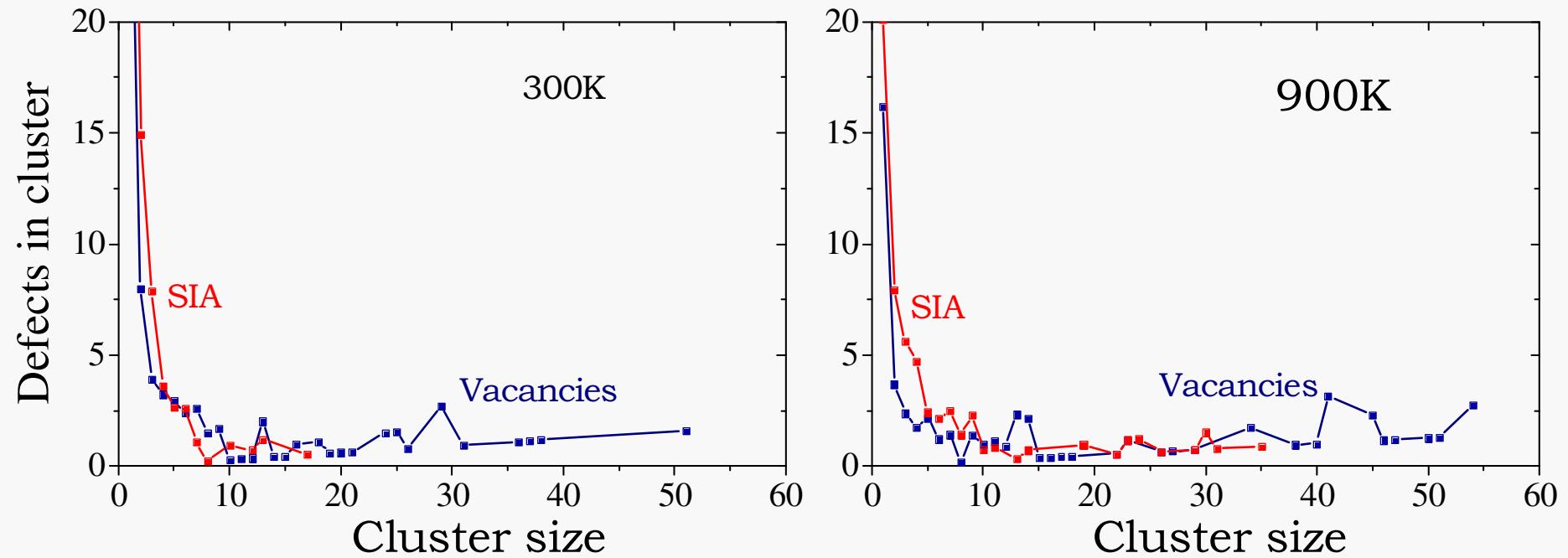
The number of the survived point defects decreases when the temperature rises.

Survived point defects fraction (AWB potential)



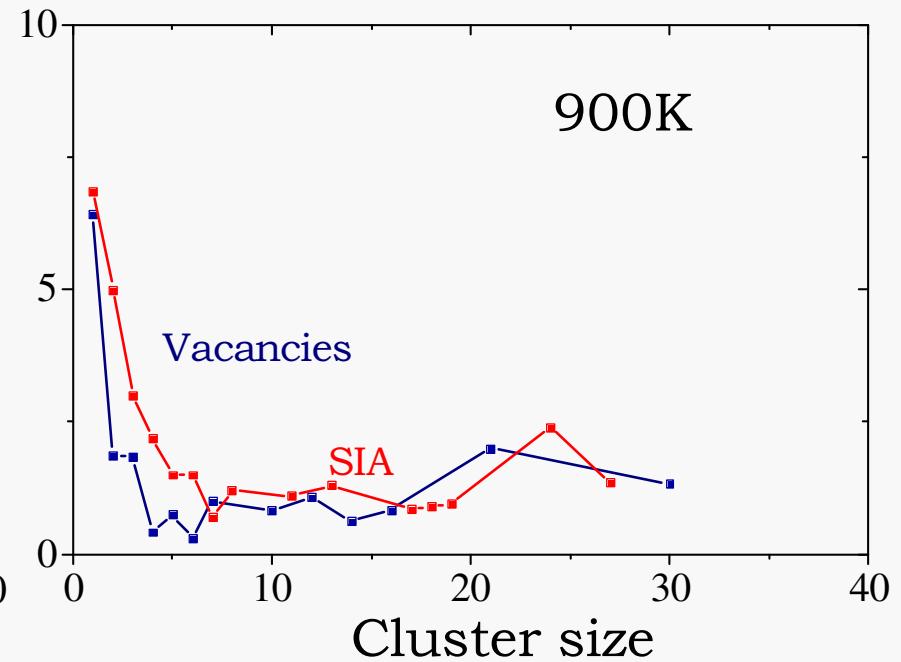
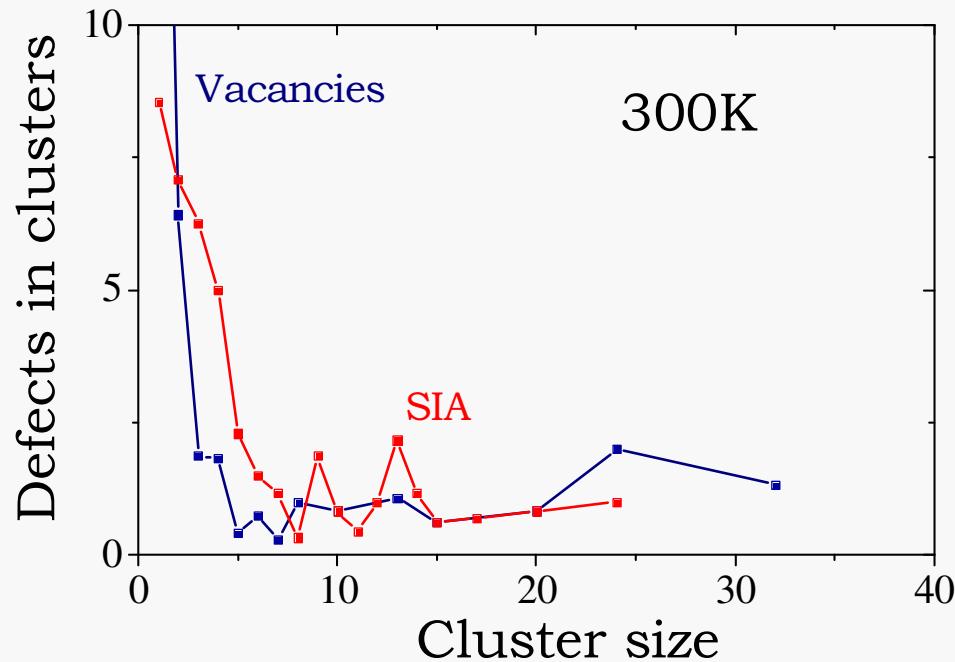
Damage production efficiency is degraded with increase of cascade energy

Distribution of cluster sizes (MA potential)



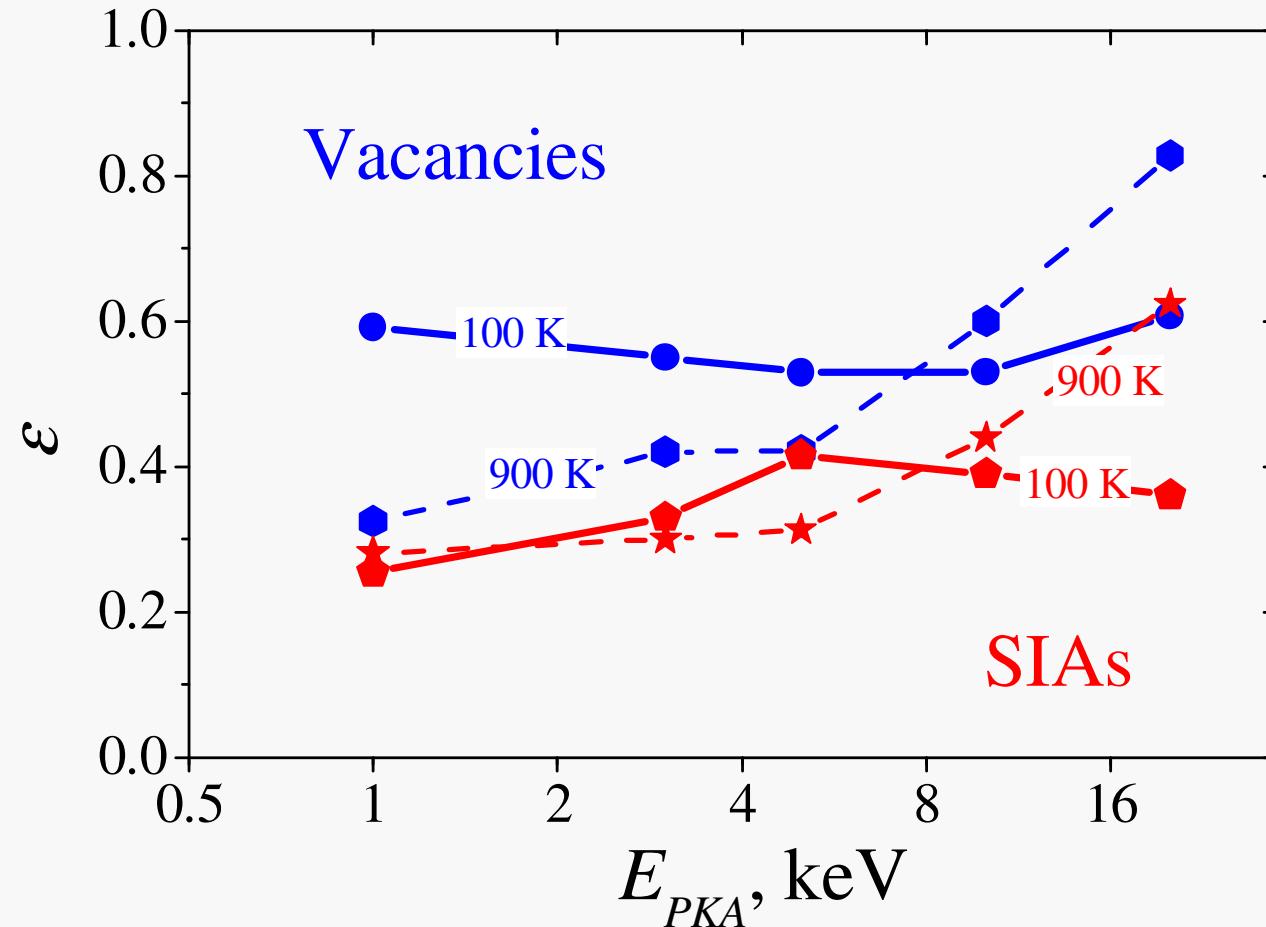
Vacancy clusters have broader distribution than SIA ones

Distribution of cluster sizes (AWB potential)



Vacancy and SIA clusters have similar distributions

Fraction of defects in clusters of size 2 and more (MA)



Conclusions

- A wide hysteresis is observed during reversible temperature-controlled MTs at MD simulation of model Zr. It is suggested that phase transformation kinetics is limited by nucleation processes in accordance with experiments
- Grain boundary affects the behavior of martensitic transformation. The hysteresis width becomes narrower indicating heterogeneous nucleation of new phase on the GB
- Local structure order parameter was implemented in the analysis of the displacive phase transformation kinetics
- Simulation of primary damage creation demonstrate increasing clusterization of point defects with PKA energy